

Beam Loss Monitoring – Detectors

Photon Detection and Silicon Photomultiplier Technology in accelerator and particle physics

Sergey Vinogradov

QUASAR group

Department of Physics, University of Liverpool, UK

Cockcroft Institute of Accelerator Science and Technology, UK

P.N. Lebedev Physical Institute of the Russian Academy of Sciences, Russia

Content



- ❑ **1. Introduction: the best photodetectors**
- ❑ **2. Silicon Photomultipliers (SiPM) as new photon number resolving detectors**
- ❑ **3. Benefits, drawbacks, and typical applications of SiPM**
- ❑ **4. Evaluation studies of SiPMs for Beam Loss Monitoring**
- ❑ **5. Modelling and analysis of comparative performance: SiPM vs PMT and APD**
- ❑ **6. Trends and prospects of SiPM technology for BLM and accelerator applications**

Introduction



- ❑ **1. Introduction: the best photodetectors**
 - ◆ your choice?

- ❑ **2. Silicon Photomultipliers (SiPM) as new photon number resolving detectors**

- ❑ **3. Benefits, drawbacks, and typical applications of SiPM**

- ❑ **4. Evaluation studies of SiPMs for Beam Loss Monitoring**

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- ❑ **6. Trends and prospects of SiPM technology for BLM and accelerator applications**

Photodetector #1 *

Adaptive focusing & trichromatic / monochromatic vision
High sensitivity due to 100 million rod cells (10-40 photons)
High resolution & double dynamic range due to 5 million cone cells
High readout rate of 30 frame/s
Internal signal processing (100M cells to 1M nerves @30fps)
540 million years old design

(*) Yu. Musienko, NDIP 2011

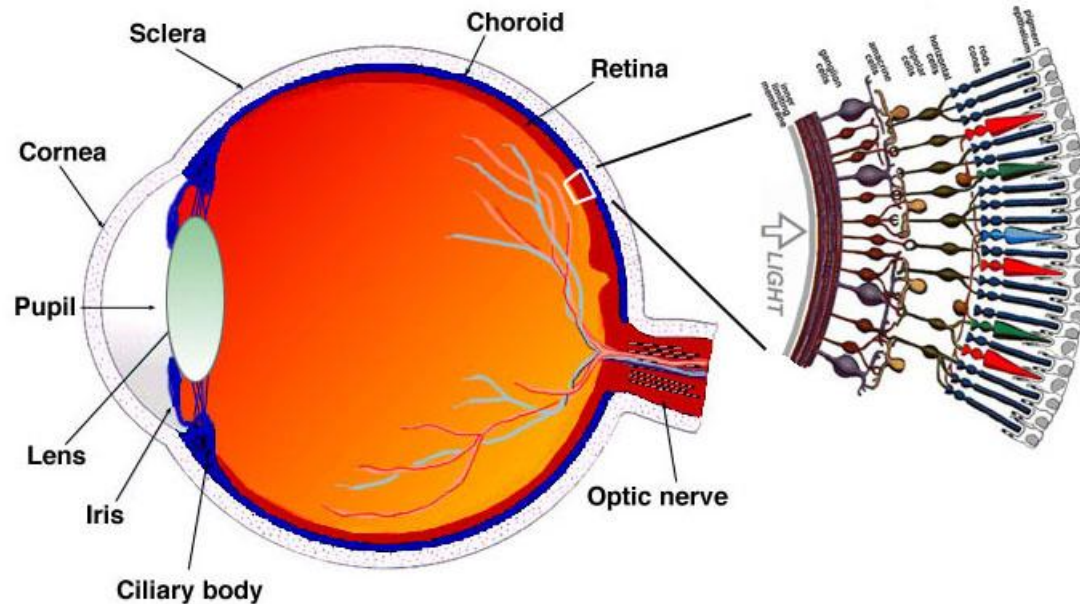


Fig. 1.1. A drawing of a section through the human eye with a schematic enlargement of the retina.

CCD/CMOS approach – toward to #1

Trichromatic / monochromatic vision
Number of pixels up to ~ 50 M
Sensitivity from ~ 10 -100 photons
Dynamic range up to ~ 50K
Readout up to ~ 1000 frame/s
40 years old design

Anatomy of a Charge Coupled Device (CCD)

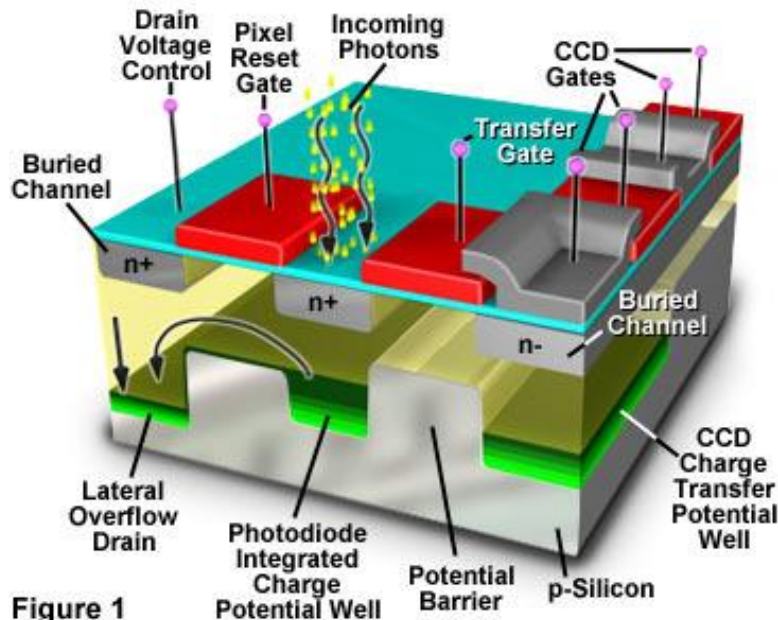


Figure 1

Full-Frame CCD Architecture

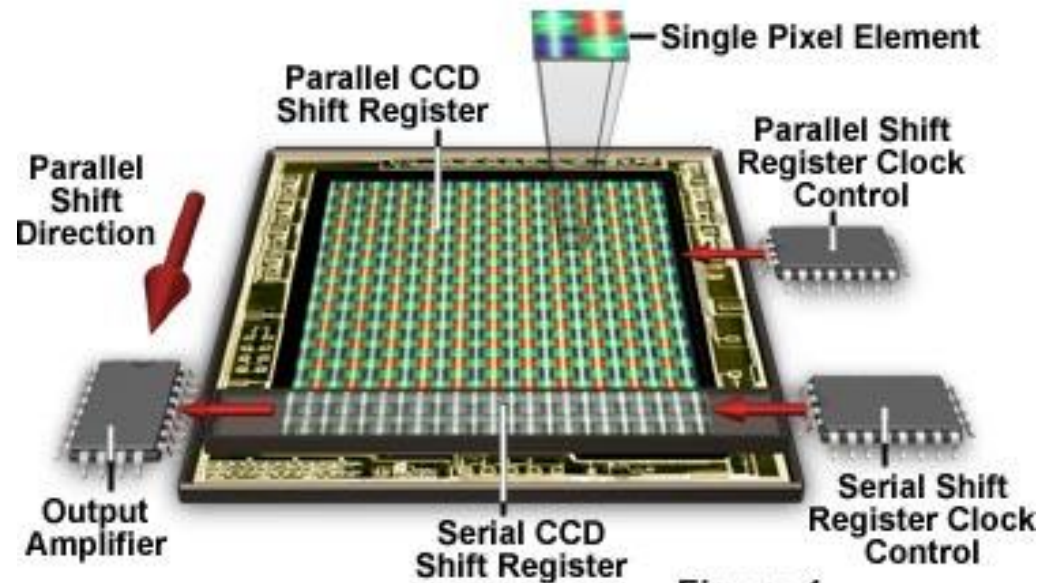
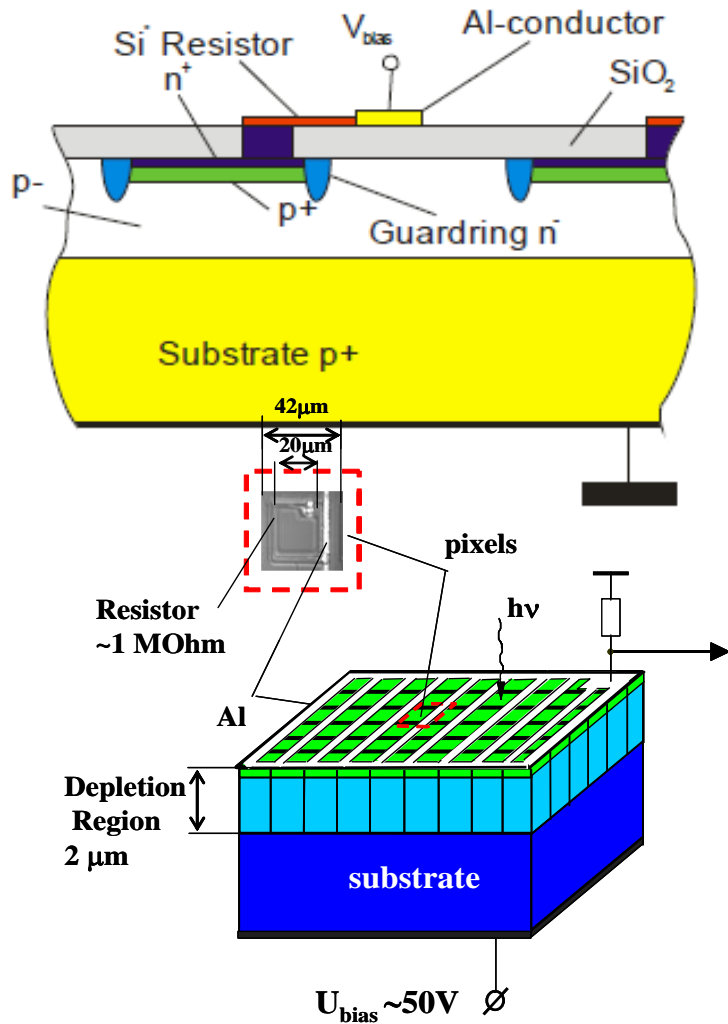


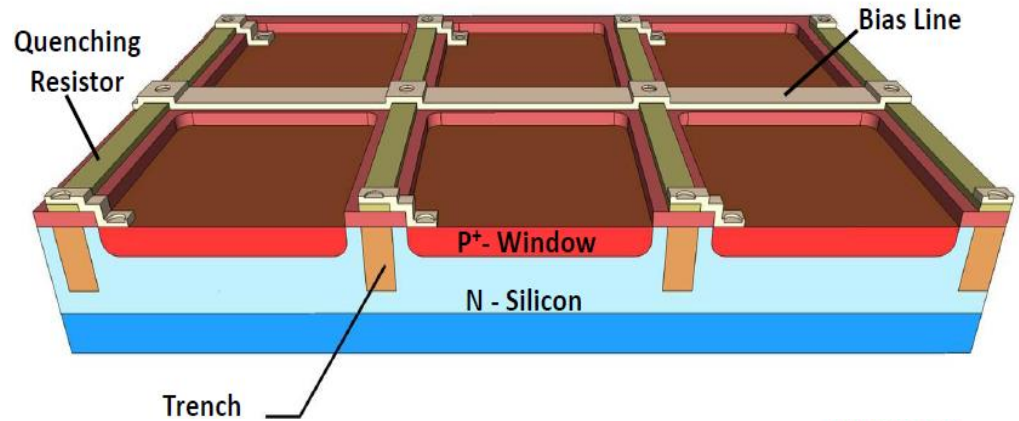
Figure 1

SiPM approach – toward to ideal low photon detection

20th Anniversary ~ now!

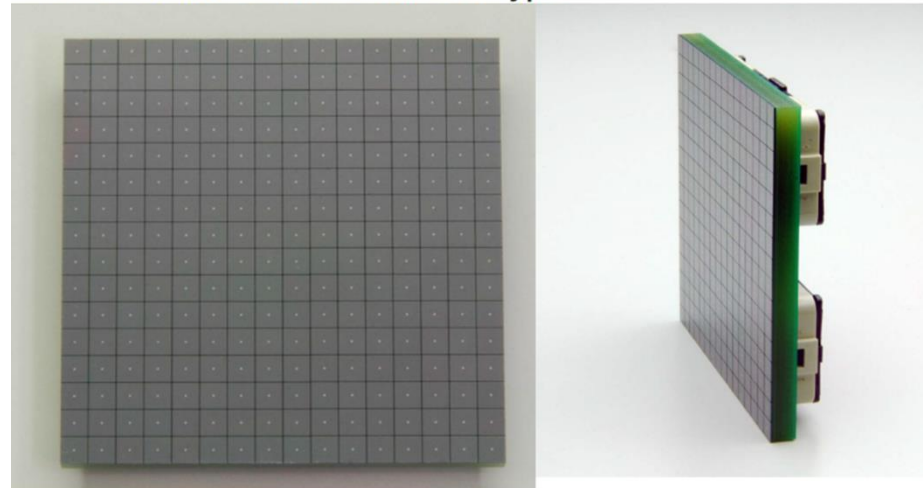


Section of KETEK SiPM Microcell



2D MPPC Array with TSV

50μm pitch, 3x3mm chip,
16x16 channels with Connector type



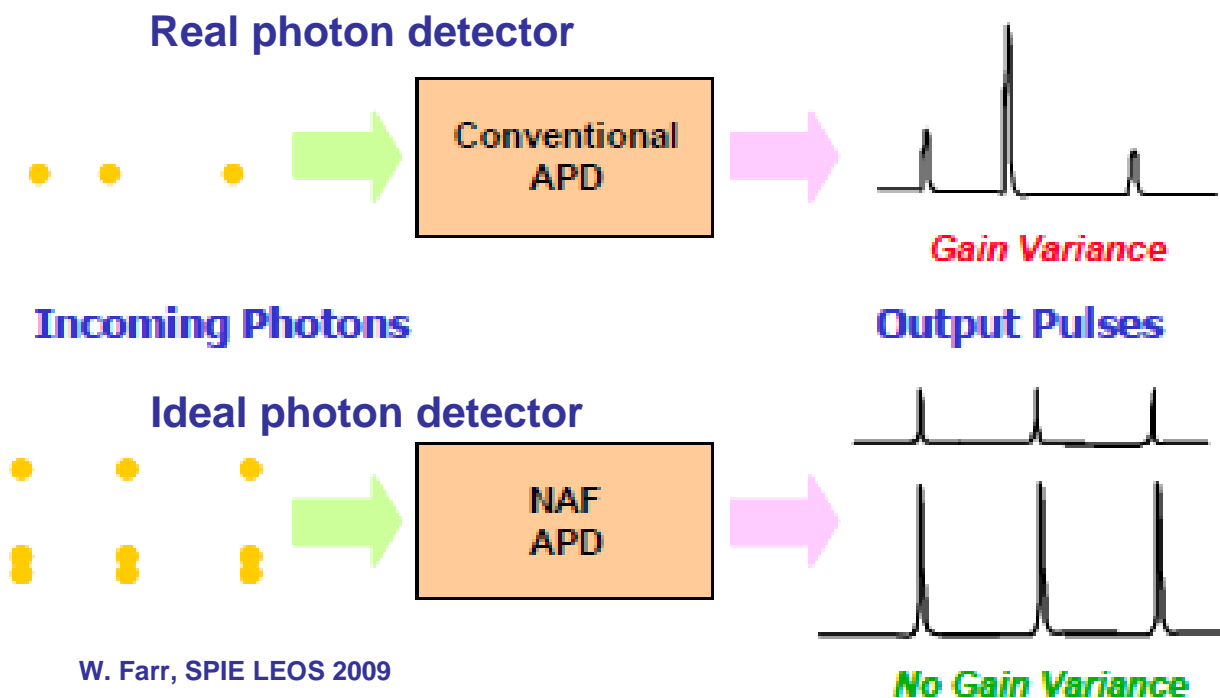
Silicon Photomultipliers (SiPM) as new photon number resolving detectors



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Concept of ideal detector: first step to SiPM

- **Ideal detector: conversion of any input signal starting from single photon to recognizable output without noise and distortion in amplitude and timing of the signal**

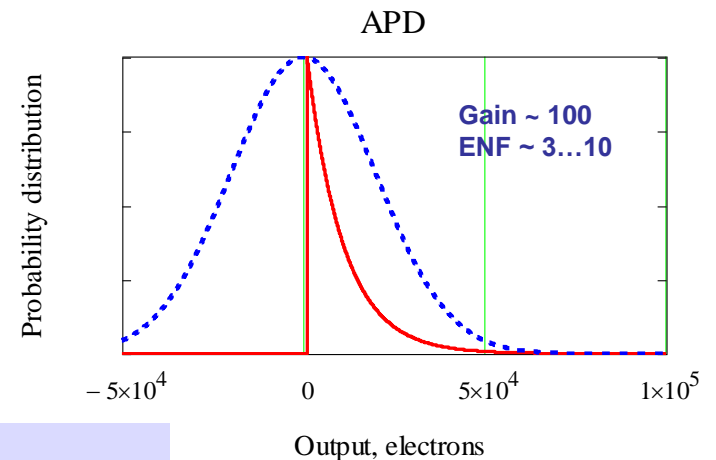
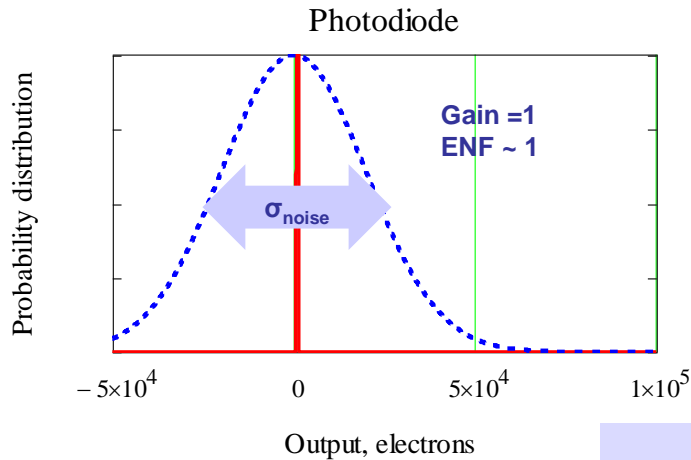


W. Farr, SPIE LEOS 2009

Single photon detection in 1 GHz BW with electronic noise $10^4 e$

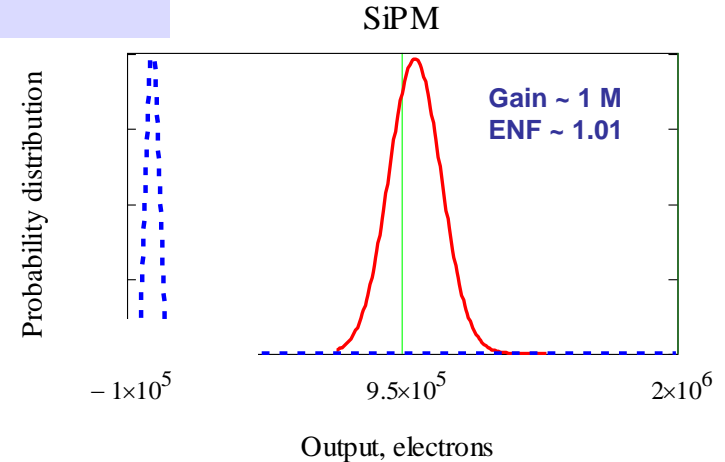
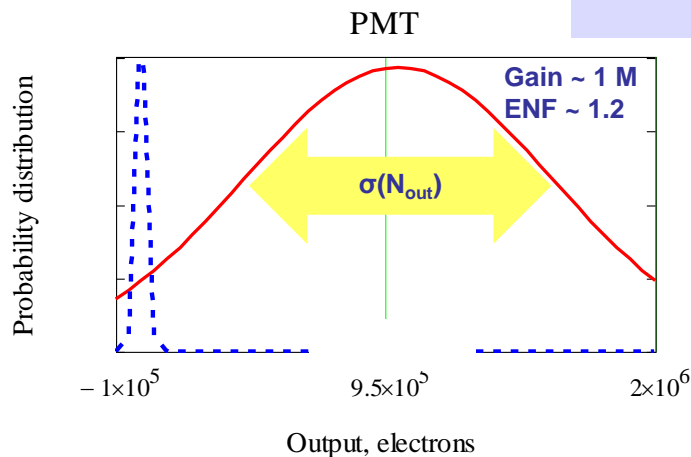


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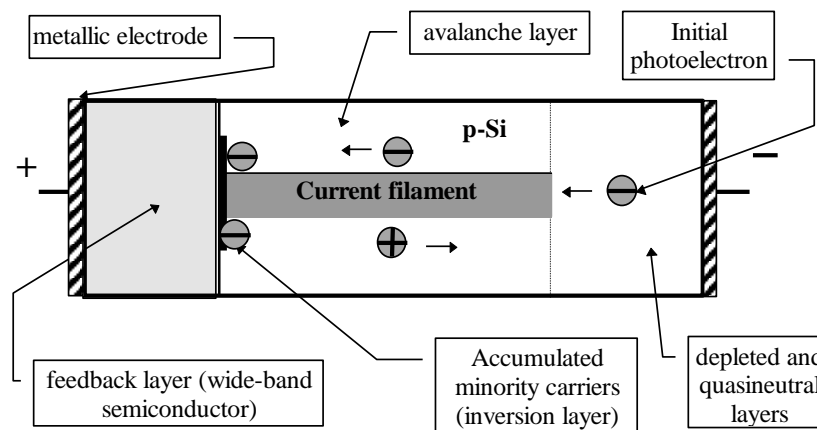
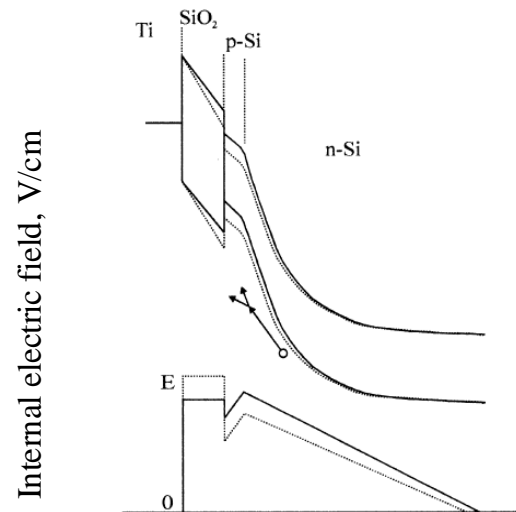
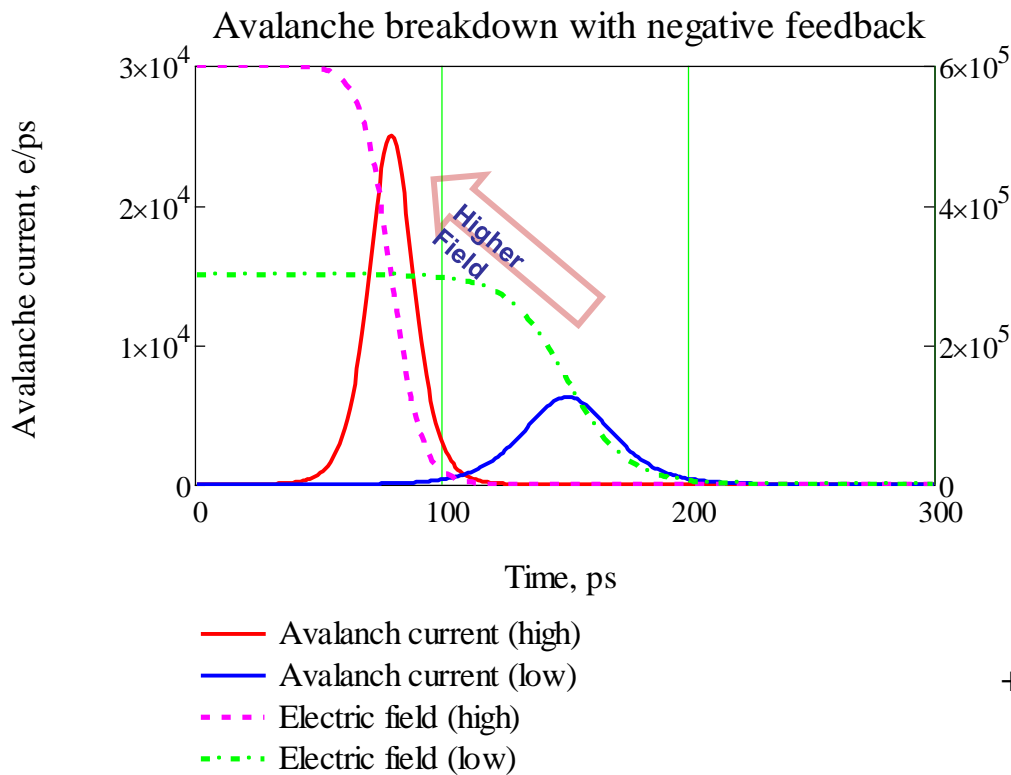
$$Resolution = \sqrt{\frac{\sigma^2(N_{out}) + \sigma^2_{noise}}{\langle N_{out} \rangle^2}}$$

$$ENF = 1 + \frac{\sigma^2(N_{out})}{\langle N_{out} \rangle^2} \quad - \text{Excess Noise Factor}$$



Avalanche with negative feedback: main step to SiPM

Strong negative feedback = fast quenching & small charge fluctuations



V. Shubin, D. Shushakov, *Avalanche Photodetectors*, 2003

Multi-pixel design & feedback resistor: final step to SiPM

MRS APD – 1990s

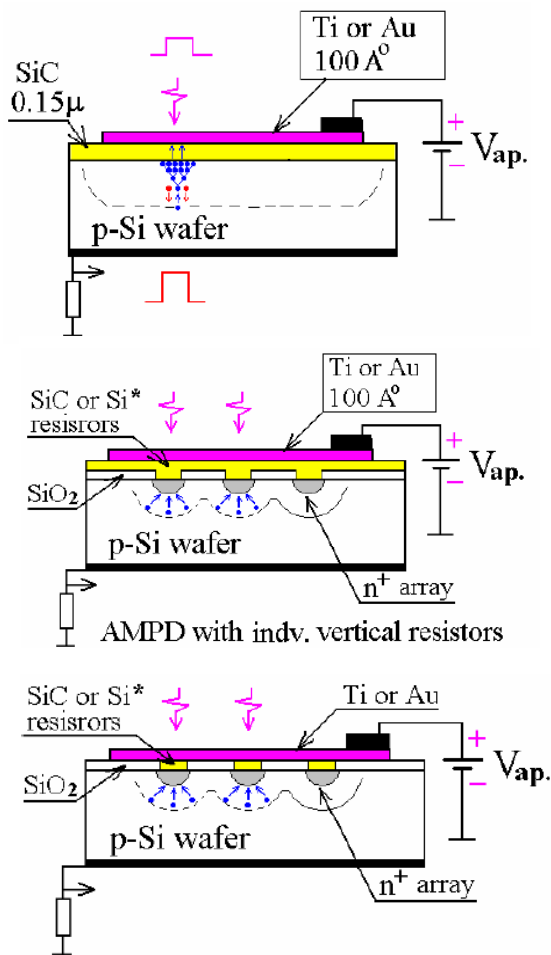


Fig. 1-4: Sadygov, NDIP 2005

SiPM – 1996 / 2000s

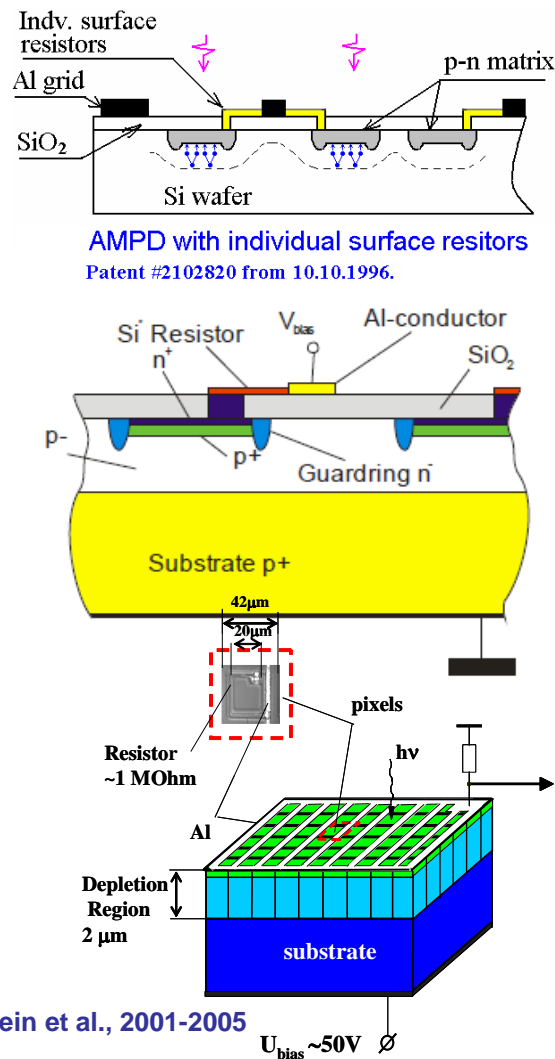
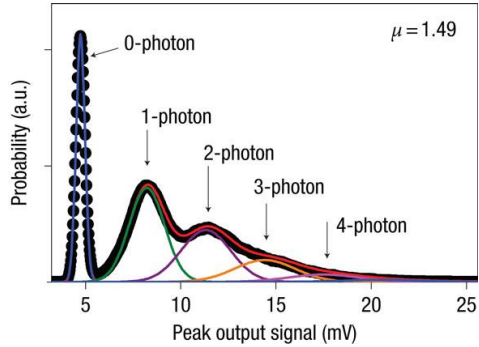


Fig. 5-7: B. Dolgoshein et al., 2001-2005

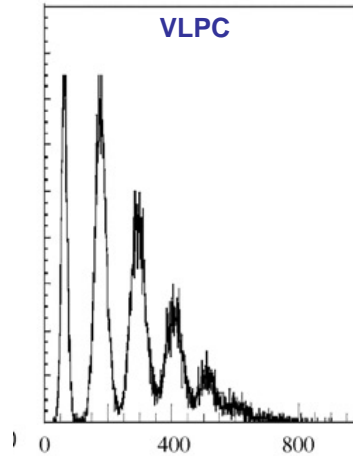
SiPM: photon number resolution

APD (self-differencing mode)

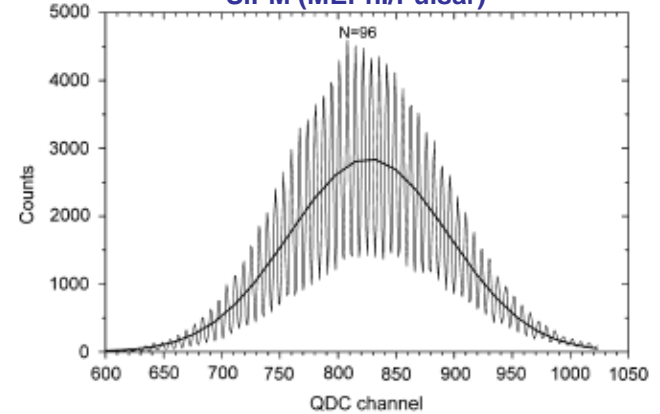


B. Kardinal et al., Nat. Photonics, 2008

VLPC

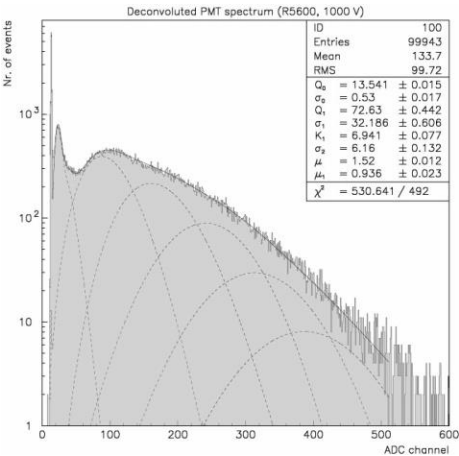


SiPM (MEPhI/Pulsar)



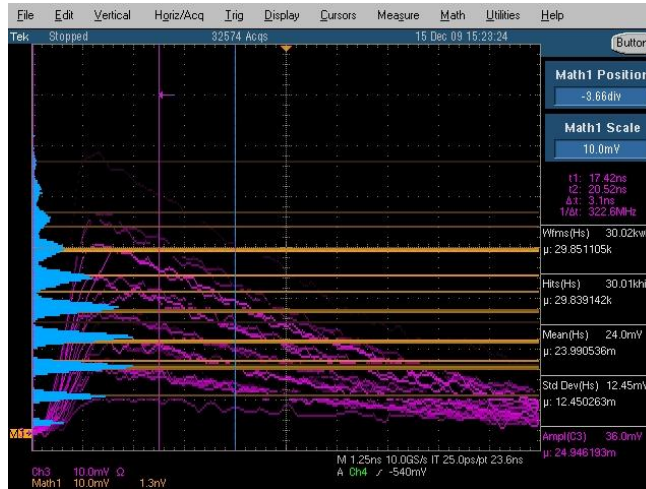
R. Mirzoyan et al., NDIP, 2008

PMT (Hamamatsu R5600)



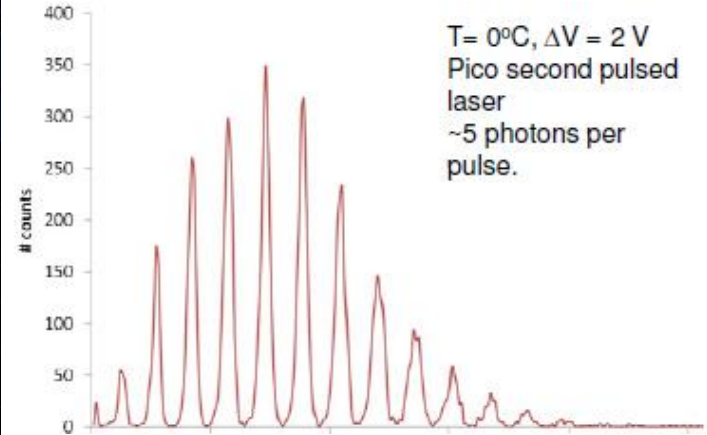
I. Chirikov-Zorin et al, NIMA 2001

MPPC (Hamamatsu)



S. Vinogradov, SPIE 2011

SiPM (Excelitas)

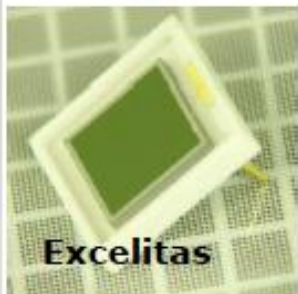
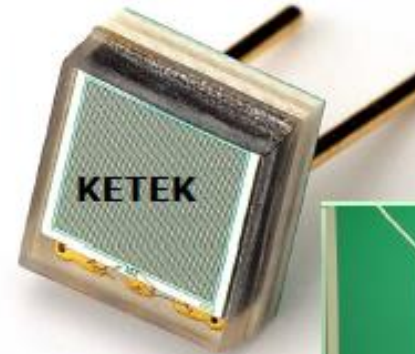
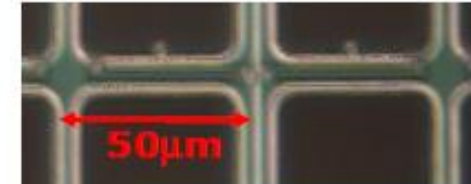
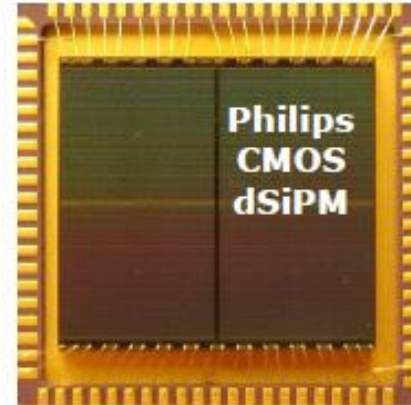
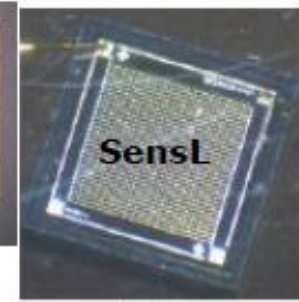


A. Barlow and J. Schilz, SiPM matching event, CERN, 2011

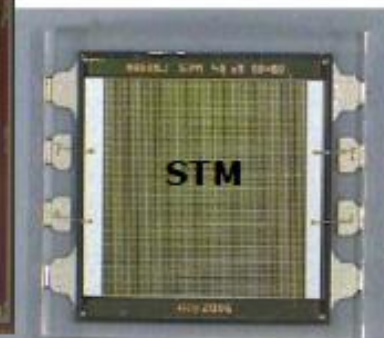
Today

Many institutes/companies are involved in SiPM development/production:

- **CPTA**, Moscow, Russia
- **MePhi/Pulsar Enterprise**, Moscow, Russia
- **Zecotek**, Vancouver, Canada
- **Hamamatsu HPK**, Hamamatsu, Japan
- **FBK-AdvanSiD**, Trento, Italy
- **ST Microelectronics**, Catania, Italy
- **Amplification Technologies** Orlando, USA
- **SensL**, Cork, Ireland
- **MPI-HLL**, Munich, Germany
- **RMD**, Boston, USA
- **Philips**, Aachen, Germany
- **Excelitas tech.** (formerly Perkin-Elmer)
- **KETEK**, Munich, Germany
- **National Nano Fab Center**, Korea
- **Novel Device Laboratory (NDL)**, Beijing, China
- **E2V**
- **CSEM**



Amplification Technologies (DAPD)



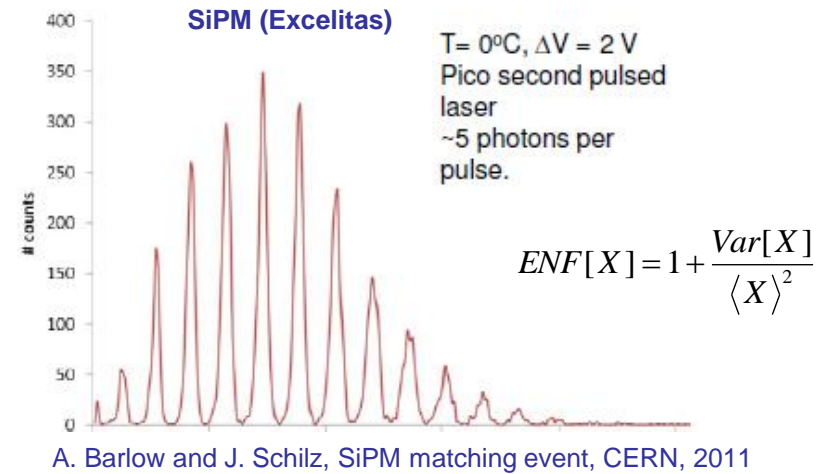
Benefits, drawbacks, and typical applications of SiPM



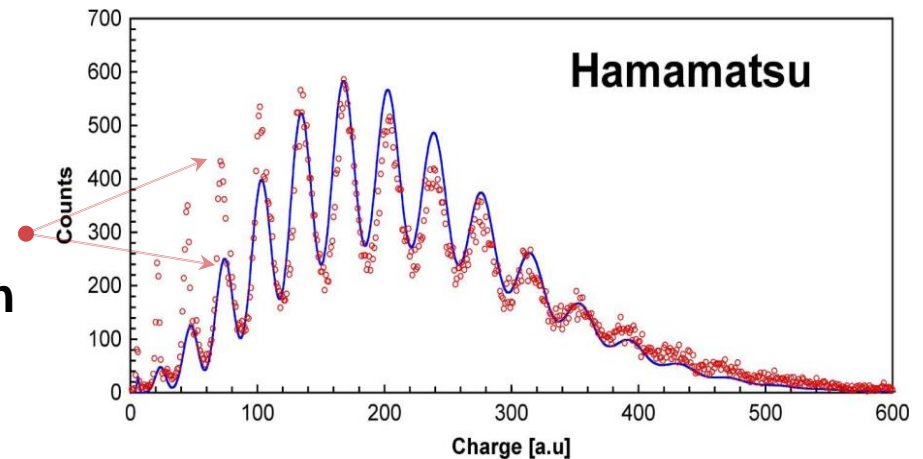
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SiPM: photon number resolution

- SiPM looks like ~ ideal detector
 - Near-ideal amplification:
 - Gain > 10⁵, ENF < 1.01
 - Room temperature
 - Low bias (<100 V)
 - Large area (6x6 mm²)
 - Good timing (jitter < 200 ps)
 - Fast response (rise <1 ns, fall ~20 ns)

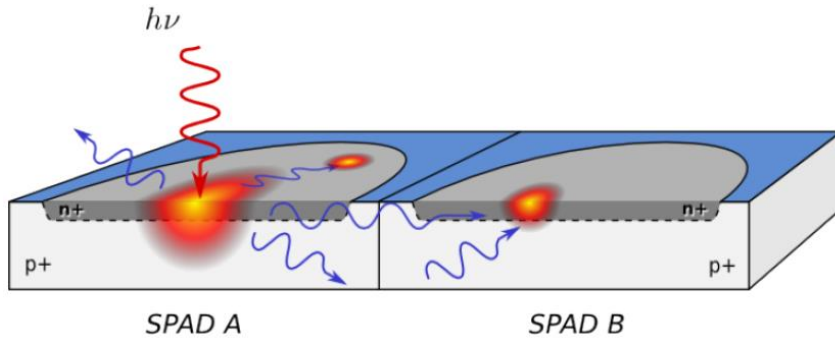


- In fact, not a photon spectrum
 - Photoelectrons
 - Dark electrons
 - Crosstalk & Afterpulses
- In fact, non-Poissonian distribution
 - Why?
 - How much?
 - Distribution?
 - Resolution?

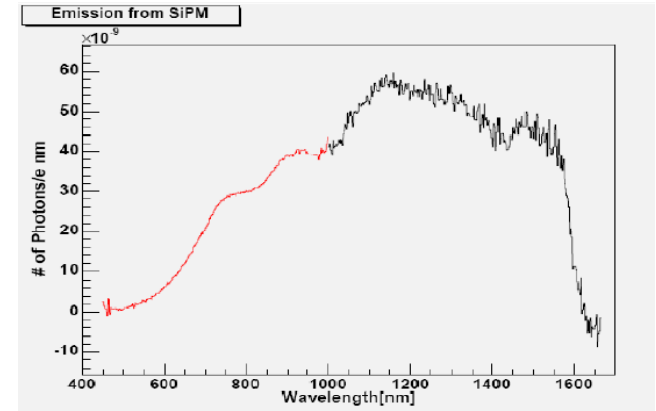


SiPM drawbacks: crosstalk

☐ Crosstalk: hot carrier photon emission + detection = false event

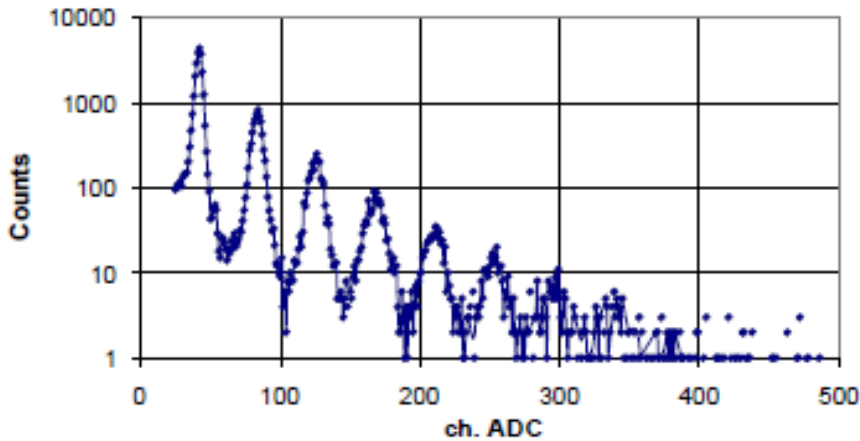


A. Lacaíta et al., IEEE TED, 1993

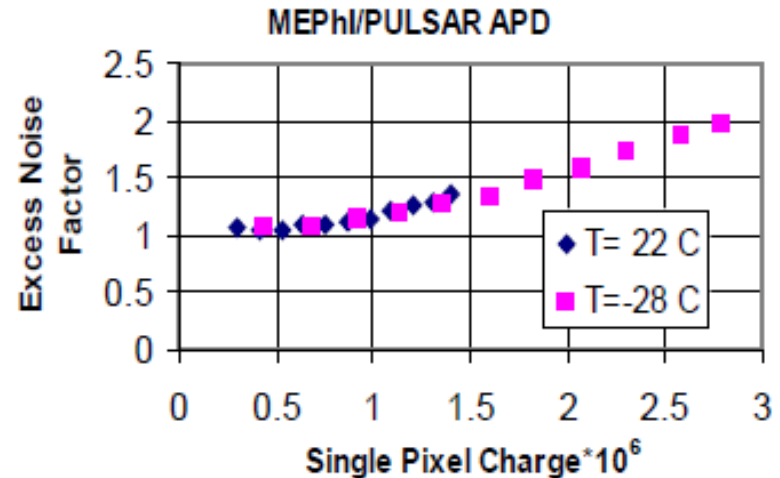


R. Mirzoyan, NDIP, 2008

SES MEPhi/PULSAR APD, $U=57.5V$, $T=-28\text{ C}$

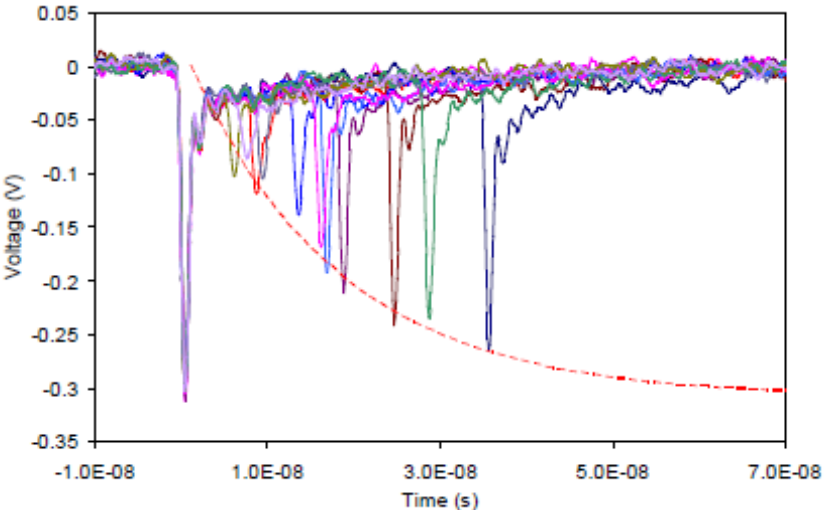
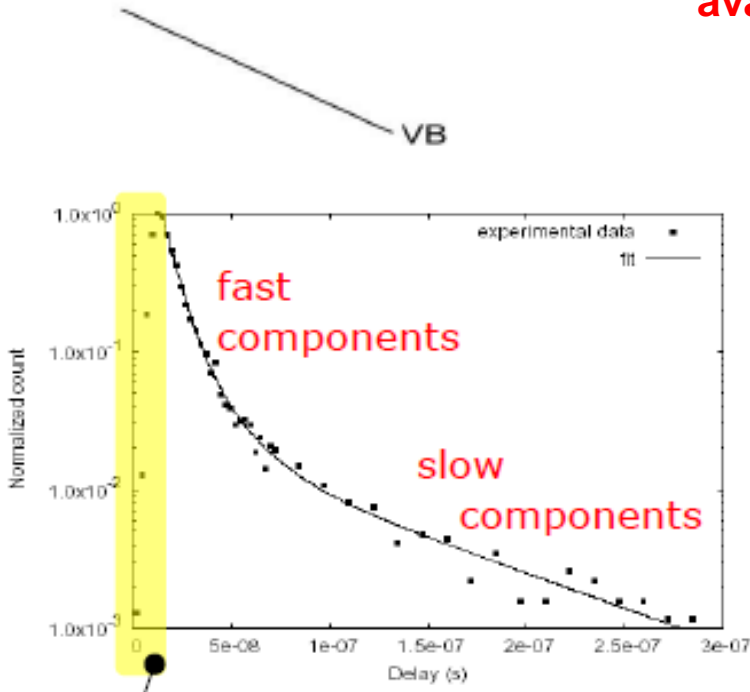
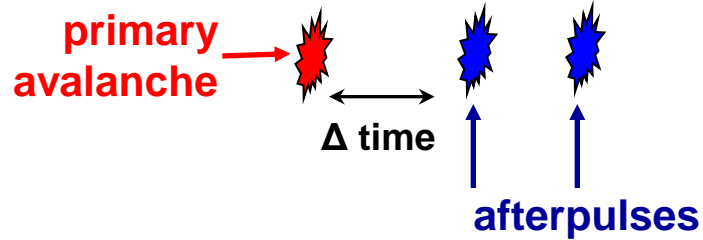
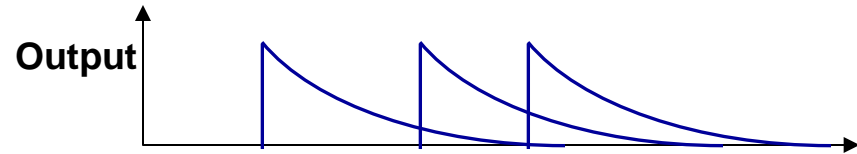
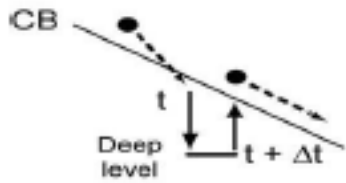


Yu. Musienko, NDIP, 2005



SiPM drawbacks: afterpulsing

Afterpulsing: trapping + detrapping + detection = false event

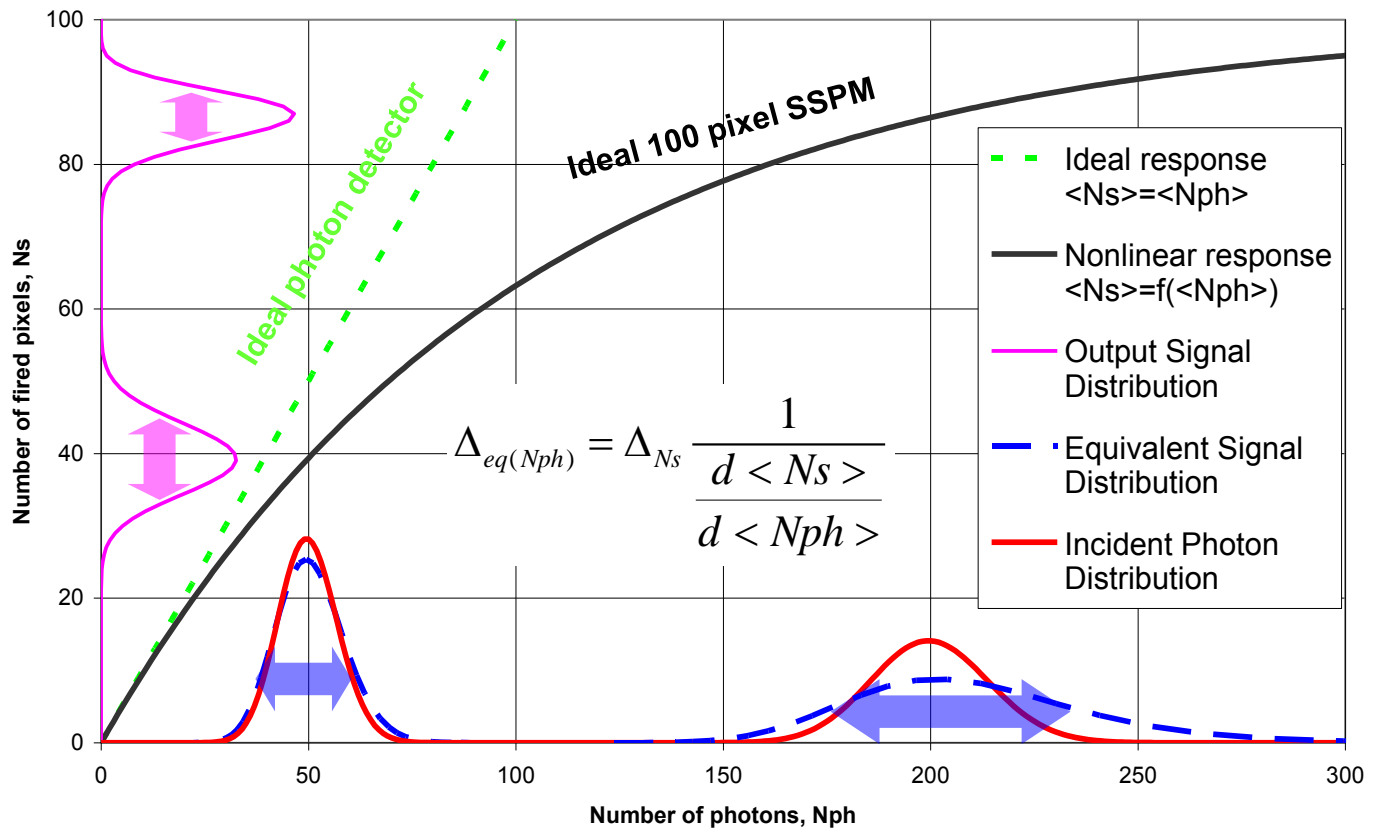


G. Collazuol, PhotoDet, 2012

C. Piemonte et al., Perugia, 2007

SiPM drawbacks: nonlinearity

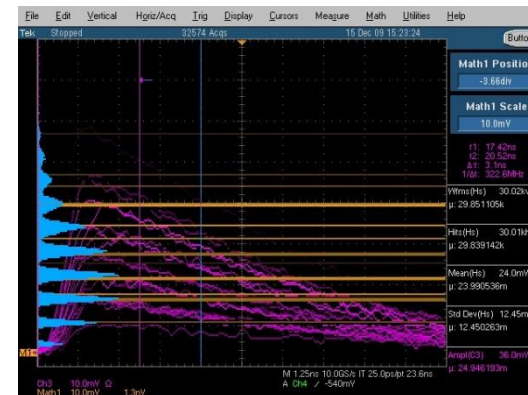
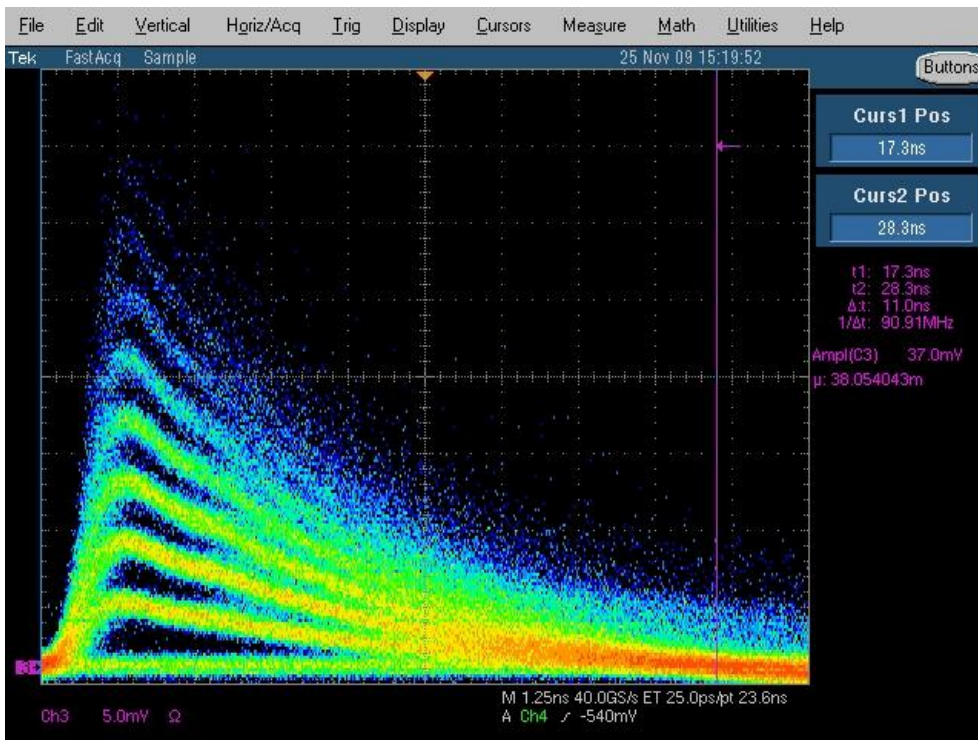
- Limited number of pixels = losses of photons
- Dead time of pixels during recovery = losses of photons



Application types



- ❑ Binary detection of light pulses – “events” (bit error rate) - NA
- ❑ Photon number resolution (noise-to-signal ratio, σ_n/μ_n) - Calorimetry
- ❑ Time-of-flight detection (transit time spread, σ_t) – TOF PET
- ❑ Detection of arbitrary signals starting from photon counting - $I_{ph}(t)$ - Beam Loss Monitoring



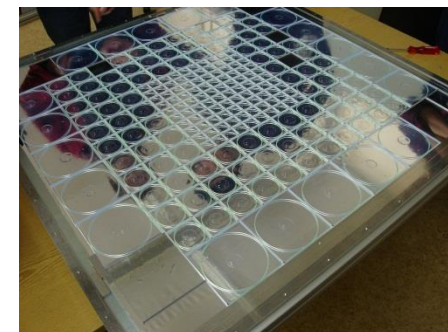
SiPM application examples



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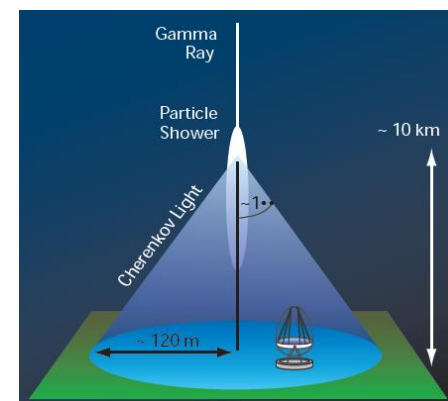
Calorimetry

- ◆ SiPM (MEPhI) small HCAL (MINICAL), DESY, 2003
- ◆ MPPC (Hamamatsu), T2K, 2005-2009
- ◆ MPPC at LHC CMS HCAL
- ◆ RICH for ALICE (LHC)
- ◆ FermiLab, Jefferson Lab calorimeter upgrade projects



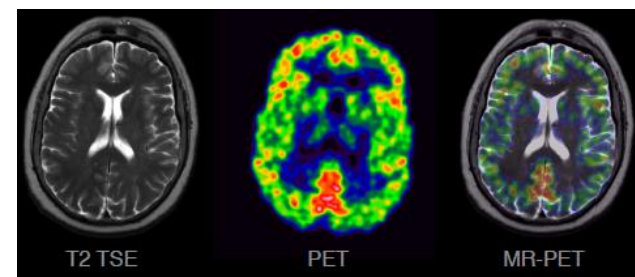
Astrophysics

- ◆ SiPM cosmic ray detection in space (MEPhI, 2005)
- ◆ Cherenkov light detection of air showers (CTA, 2013)



Medical imaging

- ◆ Positron Emission Tomography:
 - TOF-PET
 - PET / MRI



Telecommunication

- ◆ Quantum cryptography
- ◆ Deep space laser link (Mars exploring program)

Evaluation studies of SiPMs for Beam Loss Monitoring



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Beam Loss Monitoring (ref. E. Nebot talk 08-07-14)

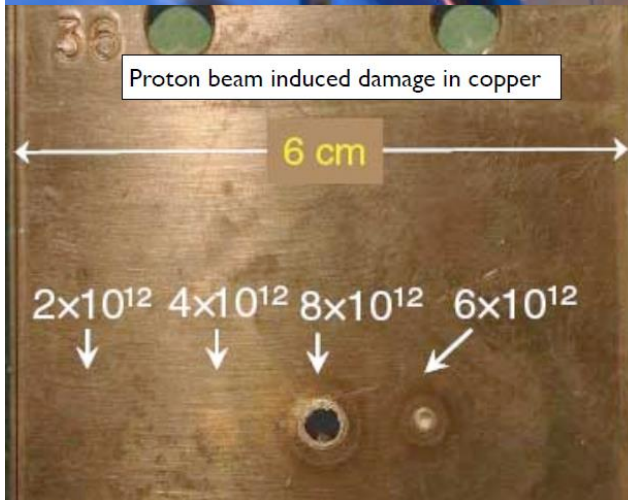


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Objectives:

**Protect
Monitor
Adjust**



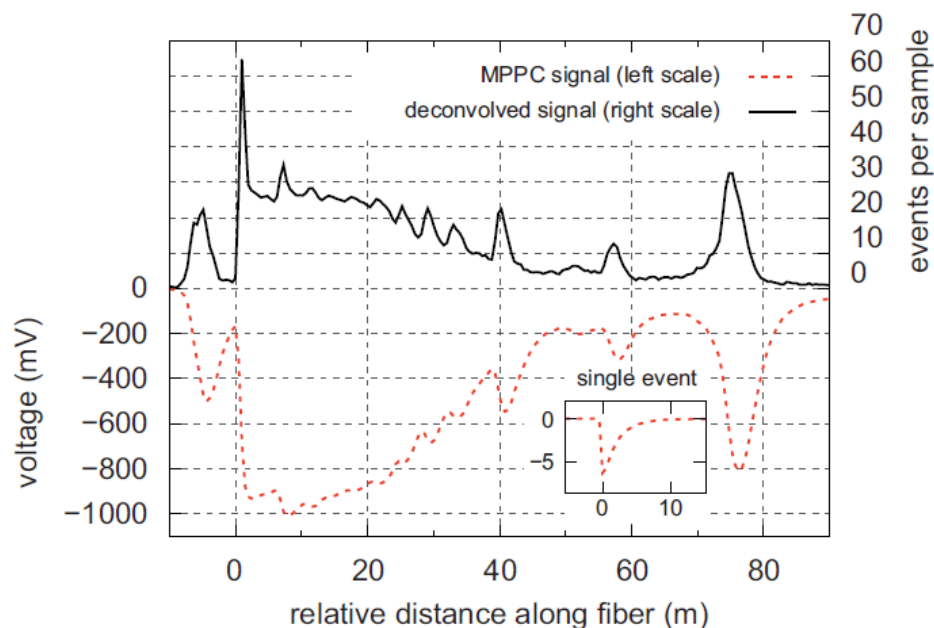
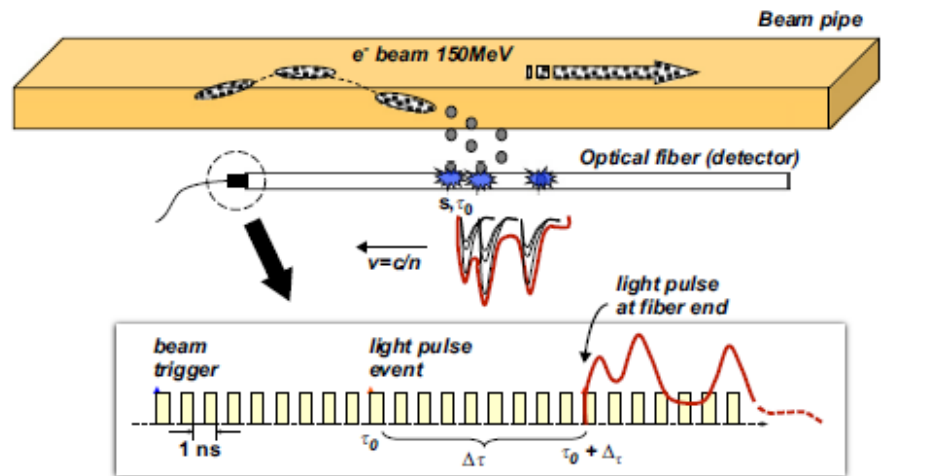
BLM: first evaluation of SiPM

D. Di Giovenale et al., NIMA, 2011
 SPARC accelerator, Frascati, INFN
 FERMI@Elettra, Sincrotrone Trieste

- ◆ MPPC, 1mm², 400 pixels
- ◆ Quartz fiber 300 μm, 100 m
- ◆ Dark count noise: negligible
- ◆ Electronic noise: negligible
- ◆ Spectral dispersion in fiber:
 $n(\lambda) \rightarrow \Delta t(\lambda) \sim 3 \text{ ns @ } 100 \text{ m}$
- ◆ $\tau_{\text{fall}} \sim 10 \text{ ns} \rightarrow \textit{deconvolution}$

Compact low cost BLM

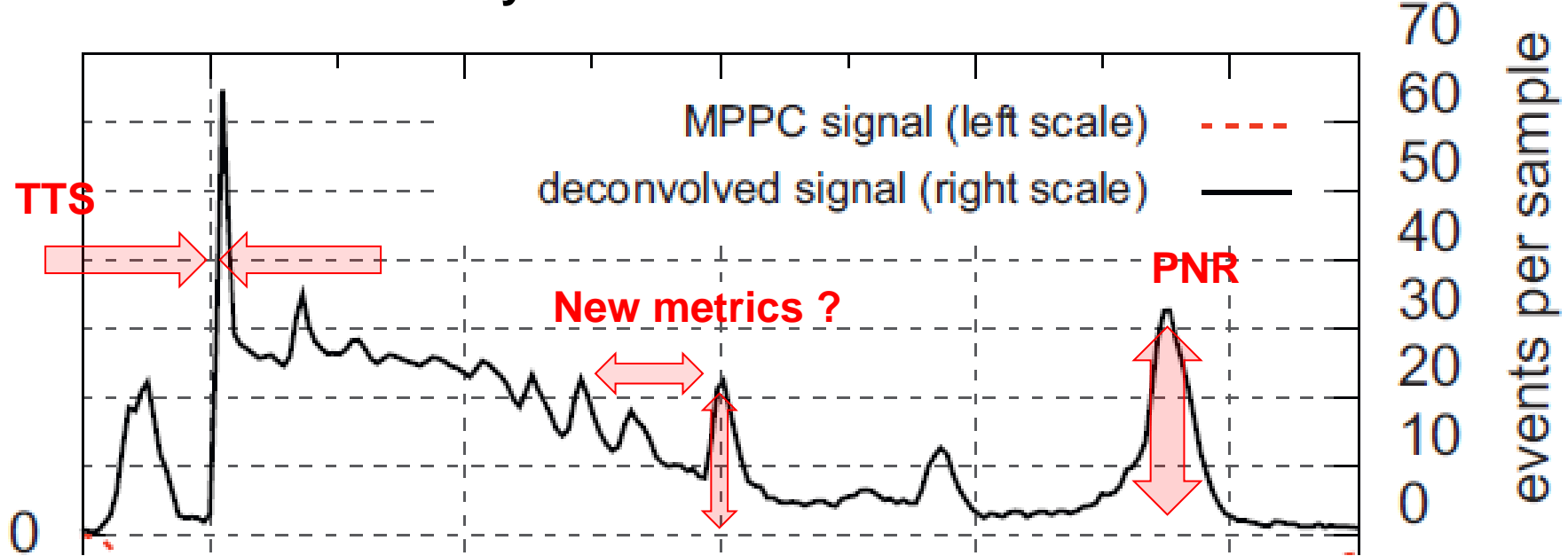
- ◆ 1m-scale resolution @ 100 m



SiPM performance metrics for BLM

Loss scenarios reconstruction

- ◆ Amplitude → # photons → # particles per location (PNR)
- ◆ Transit time to rising edge → single loss location (Time Res.)
- ◆ Resolution of multiple loss locations & # particles
 - Modulation transfer function (MTF) ?
 - Nonlinearity has to be accounted !



Challenges for SiPM in BLM: saturation, recovering, duplications

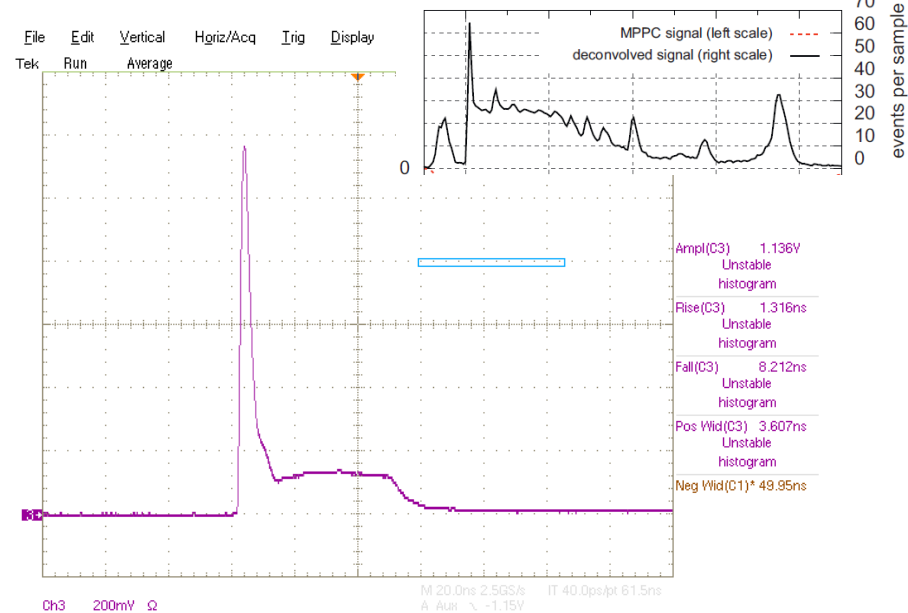
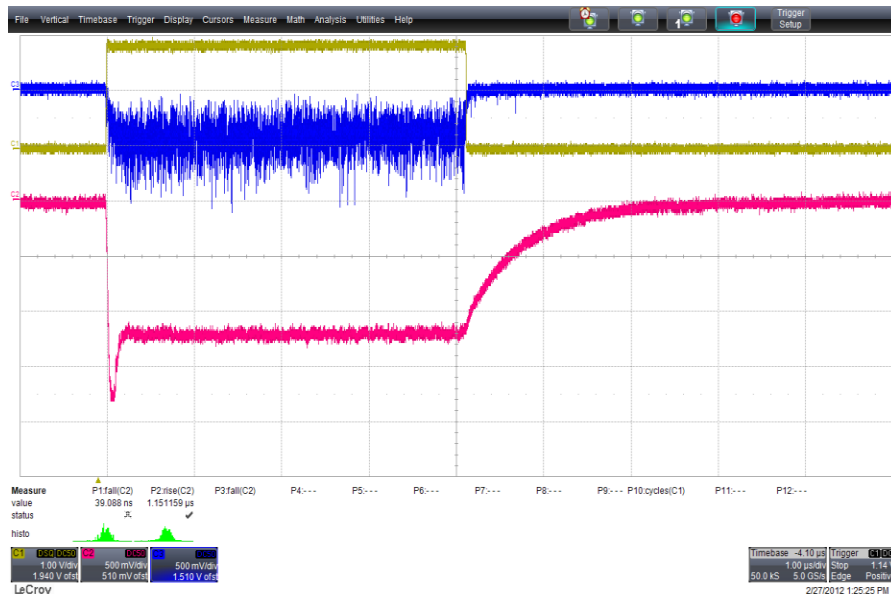
Transient nonlinearity of SiPM response

Large rectangular light pulse: $N_{ph} > N_{pix}$; $T_{pulse} > T_{rec}$

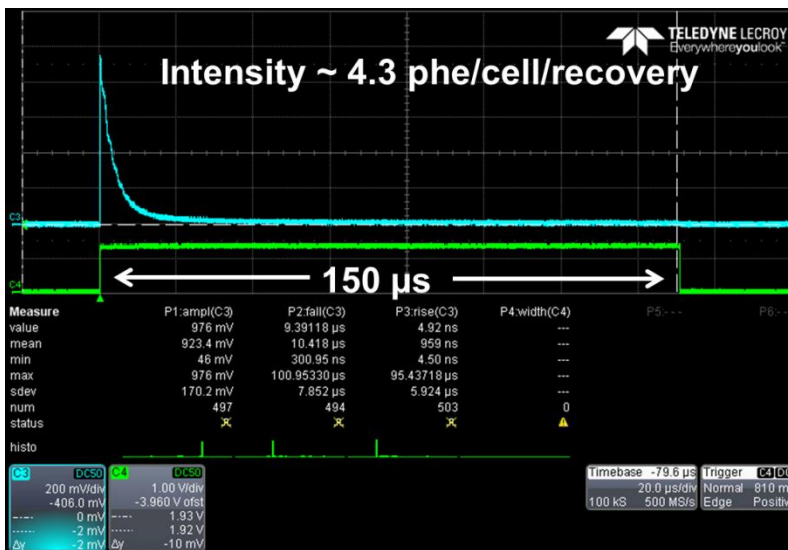
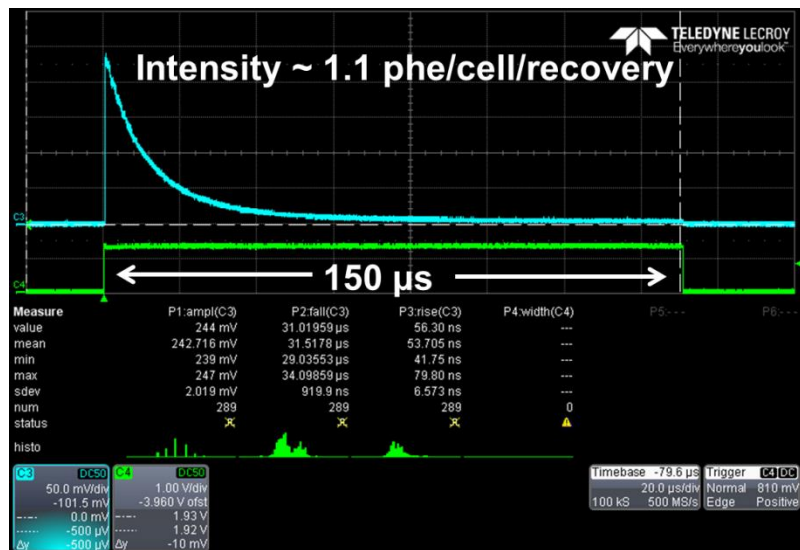
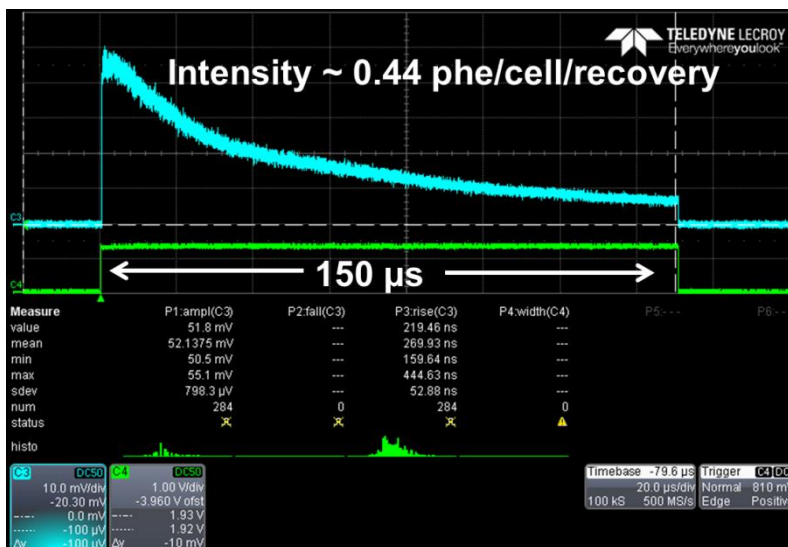
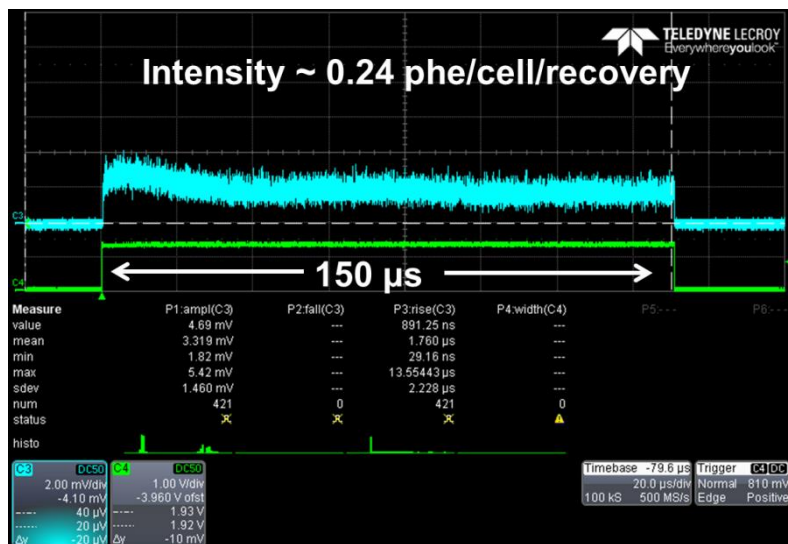
- ◆ Peak – initial avalanche events in ready-to-triggering pixels
- ◆ Plateau – repetitive recovering and re-triggering of pixels
- ◆ Fall – final recovering (without photons, but with afterpulses!)

4 us pulse

50 ns pulse



MPPC response on rectangular pulse



Modelling and analysis of comparative performance: SiPM vs PMT and APD



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Photon Number Resolution

Photon Number Resolution & Excess Noise Factor

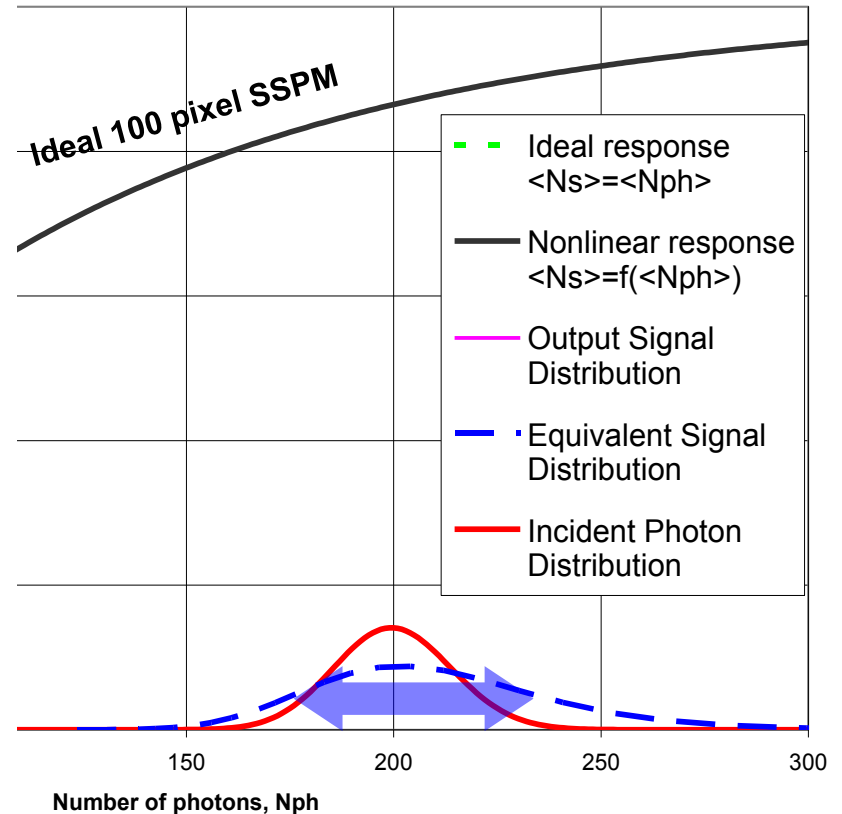
Burgess variance theorem

$$ENF_1 = 1 + \frac{\sigma(N_{out})^2}{\langle N_{out} \rangle^2} \quad \text{if } N_{in} \equiv 1$$

$$ENF_N = \frac{\sigma(N_{out})^2}{\langle N_{out} \rangle^2} \bigg/ \frac{\sigma(N_{in})^2}{\langle N_{in} \rangle^2} \quad \text{if } N_{in} - \text{random}$$

$$PNR_{out} = \frac{\sigma(N_{out})}{\langle N_{out} \rangle} = \frac{\sigma(N_{in})}{\langle N_{in} \rangle} \cdot \sqrt{ENF_N}$$

$$\text{if } N_{in} - \text{Poissonian} \Rightarrow ENF_N = ENF_1$$



Schematics of AP & CT stochastic processes

Duplication Models	Single primary event $N \equiv 1$ e.g. SSPM Dark Spectrum	Poisson number of primaries $\langle N \rangle = \mu$ e.g. SSPM Photon Spectrum
Geometric Chain Afterpulsing Process	<p style="text-align: center;">Non-random (Dark) event</p> <p style="text-align: center;"> </p> <p style="text-align: center;"> Primary 1st CT 2nd CT No CT </p> <p style="text-align: center;">Random CT events</p>	<p style="text-align: center;">Random primary (Photo) events</p> <p style="text-align: center;"> </p> <p style="text-align: center;">Random CT events</p>
Branching Poisson Crosstalk Process	<p style="text-align: center;">Non-random (Dark) event</p> <p style="text-align: center;"> </p> <p style="text-align: center;">Random CT events</p>	<p style="text-align: center;">Random primary (Photo) events</p> <p style="text-align: center;"> </p> <p style="text-align: center;">Random CT events</p>

CT & AP model results



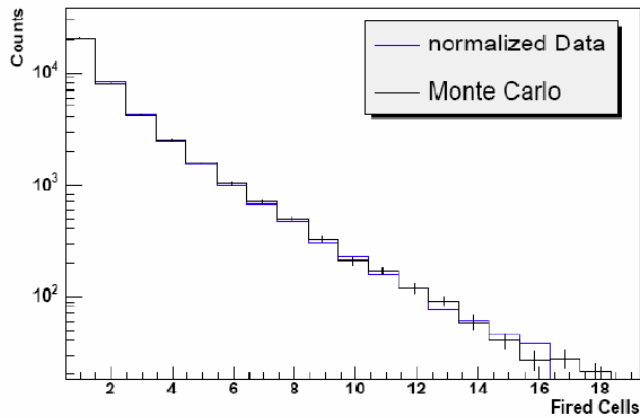
Results	Geometric chain process		Branching Poisson process	
	Non-random single ($N=1$)	Poisson (μ)	Non-random single ($N=1$)	Poisson (μ)
Total event distribution	Geometric (p)	Compound Poisson (μ, p)	Borel (λ)	Generalized Poisson (μ, λ)
$P(X=k)$	$p^{k-1} \cdot (1-p)$	Ref. [1]	$\frac{(\lambda \cdot k)^{k-1} \cdot \exp(-k \cdot \lambda)}{k!}$	$\frac{\mu \cdot (\mu + \lambda \cdot k)^{k-1} \cdot \exp(-\mu - k \cdot \lambda)}{k!}$
$E[X]$	$\frac{1}{1-p}$	$\frac{\mu}{1-p}$	$\frac{1}{1-\lambda}$	$\frac{\mu}{1-\lambda}$
$Var[X]$	$\frac{p}{(1-p)^2}$	$\frac{\mu \cdot (1+p)}{(1-p)^2}$	$\frac{\lambda}{(1-\lambda)^3}$	$\frac{\mu}{(1-\lambda)^3}$
ENF	$1+p$		$\frac{1}{1-\lambda} \approx 1+p + \frac{3}{2}p^2 + o(p^3)...$	

[1] S. Vinogradov et al., NSS/MIC 2009

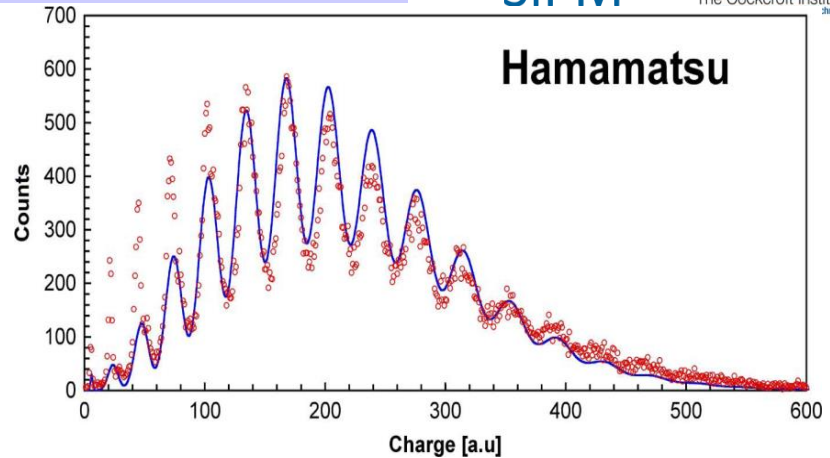
λ is a mean number of successors in one branch generation

Crosstalk models and experiments

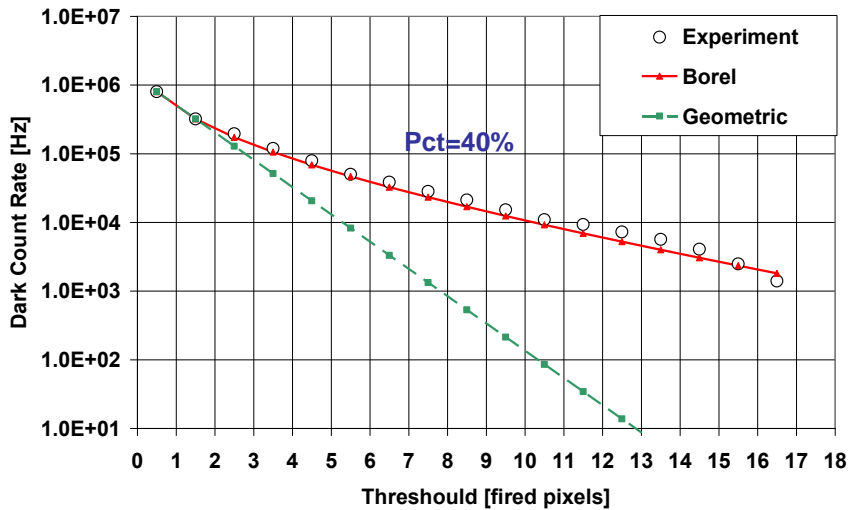
Crosstalk Distribution



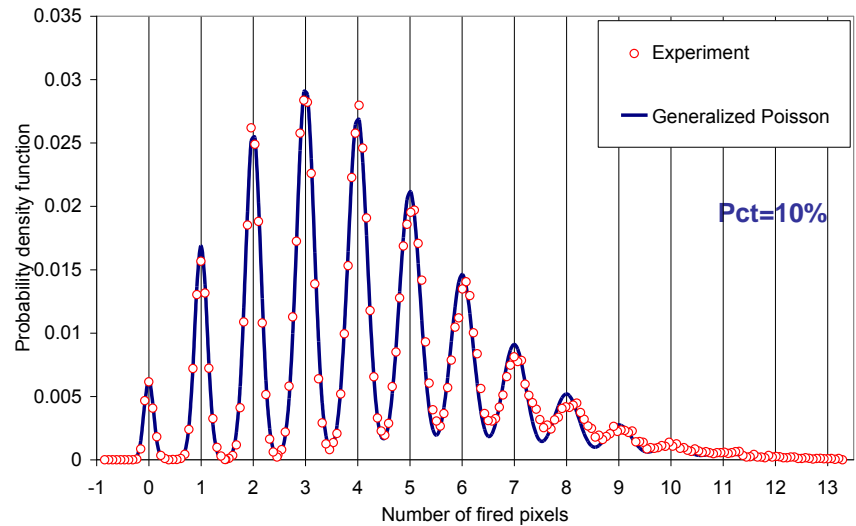
A.N. Otte, JINST 2007



P. Finocchiaro et al., IEEE TNS, 2009

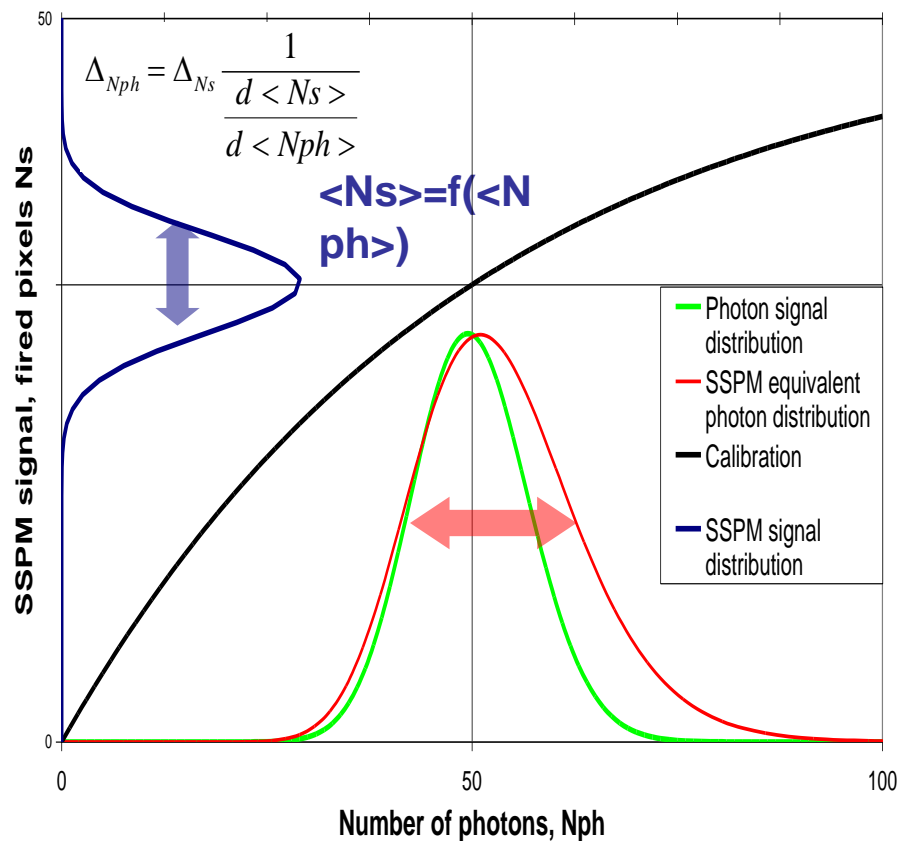
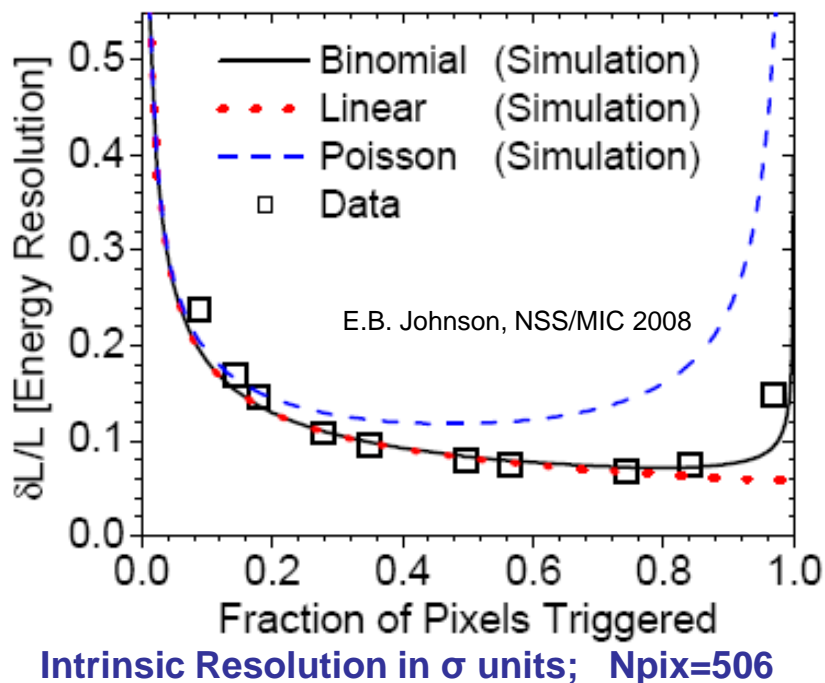
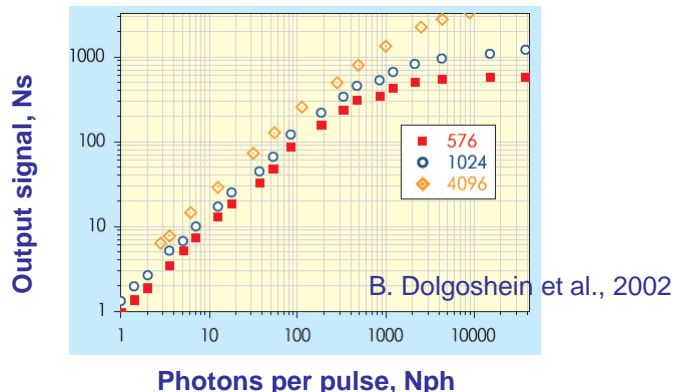


Dark event complementary cumulative distribution – DCR vs. threshold
 (S. Vinogradov, NDIP 2011; experiment B. Dolgoshein et al., NDIP 2008)



A few photon detection spectrum of Hamamatsu MPPC
 (S. Vinogradov, SPIE 2012)

SiPM binomial nonlinearity



$$\overline{N_{fired}} = N_{cell} \cdot \left(1 - e^{-\frac{N_{ph} \cdot PDE}{N_{cell}}} \right)$$

$$\sigma_{N_{fired}}^2 = N_{cell} \cdot \left(1 - e^{-\frac{N_{ph} \cdot PDE}{N_{cell}}} \right) \cdot e^{-\frac{N_{ph} \cdot PDE}{N_{cell}}}$$

$$ENF = \frac{e^{\frac{N_{ph} \cdot PDE}{N_{cell}}} - 1}{\frac{N_{ph} \cdot PDE}{N_{cell}}}$$

SiPM recovery nonlinearity

$$T_{pulse} \gg T_{rec}$$

Nonparalizable dead time model Probability distribution (~ Gaussian)

W. Feller, *An Introduction to Probability Theory and Its Applications*, Vol. 2, Ch. XI, John Wiley & Sons, Inc., 1968

$$\mu_{Ns} = \frac{\lambda \cdot t}{1 + \lambda \cdot \tau_{dead}}$$

$$\sigma^2_{Ns} = \frac{\lambda \cdot t}{(1 + \lambda \cdot \tau_{dead})^3}$$

Recovery non-linearity → ENF

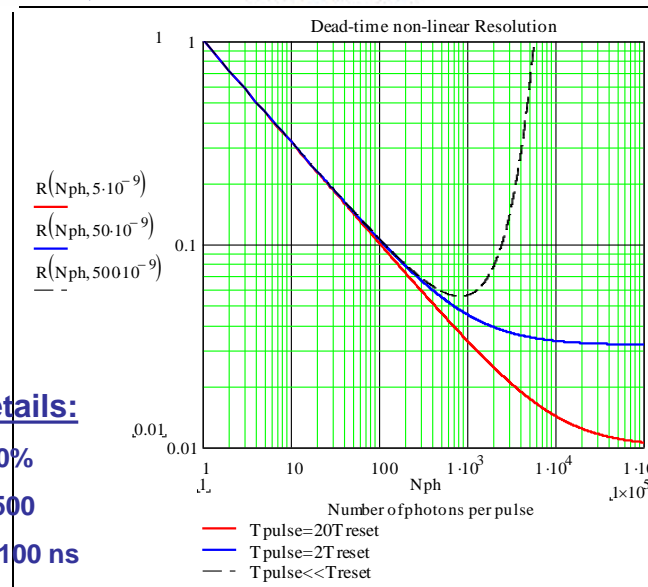
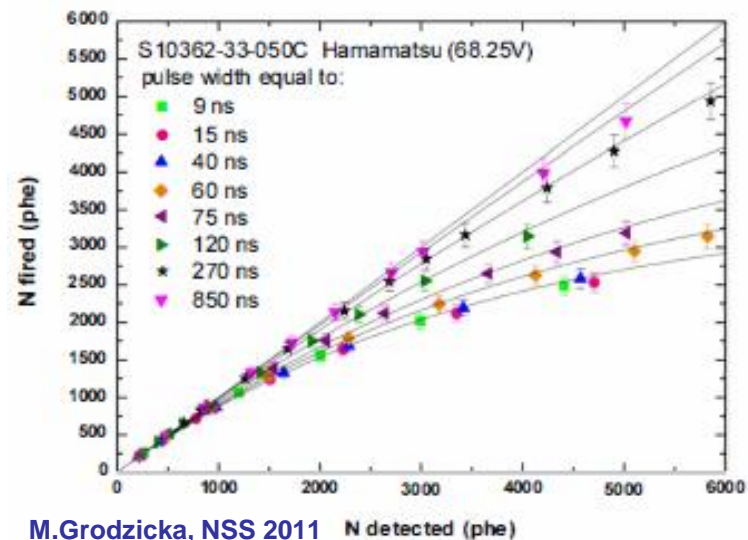
S. Vinogradov et al., IEEE NSS/MIC 2009

$$ENF_{eq(N_{ph})}(\lambda) = 1 + \lambda \cdot \tau_{dead}$$

2) Exponential recovery of Gain m(t) accounting for Pdet(m)

S. Vinogradov, SPIE DSS, 2012

$$ENF_{eq(N_{ph})}(\lambda) = \frac{(1 + \lambda \cdot \tau_{rec})^3}{1 + \frac{\lambda \cdot \tau_{rec}}{2}} \quad \left\{ \text{if } P_{det}(m) = const \right\}$$



Performance metrics: ENF and DQE



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SiPM



The Cockcroft Institute
of Accelerator Science and Technology



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$$PNR_{out} = \frac{\sigma(N_{out*})}{\mu(N_{out*})} = PNR_{in}(Nph) \cdot \sqrt{ENF_{total}(Nph)}$$

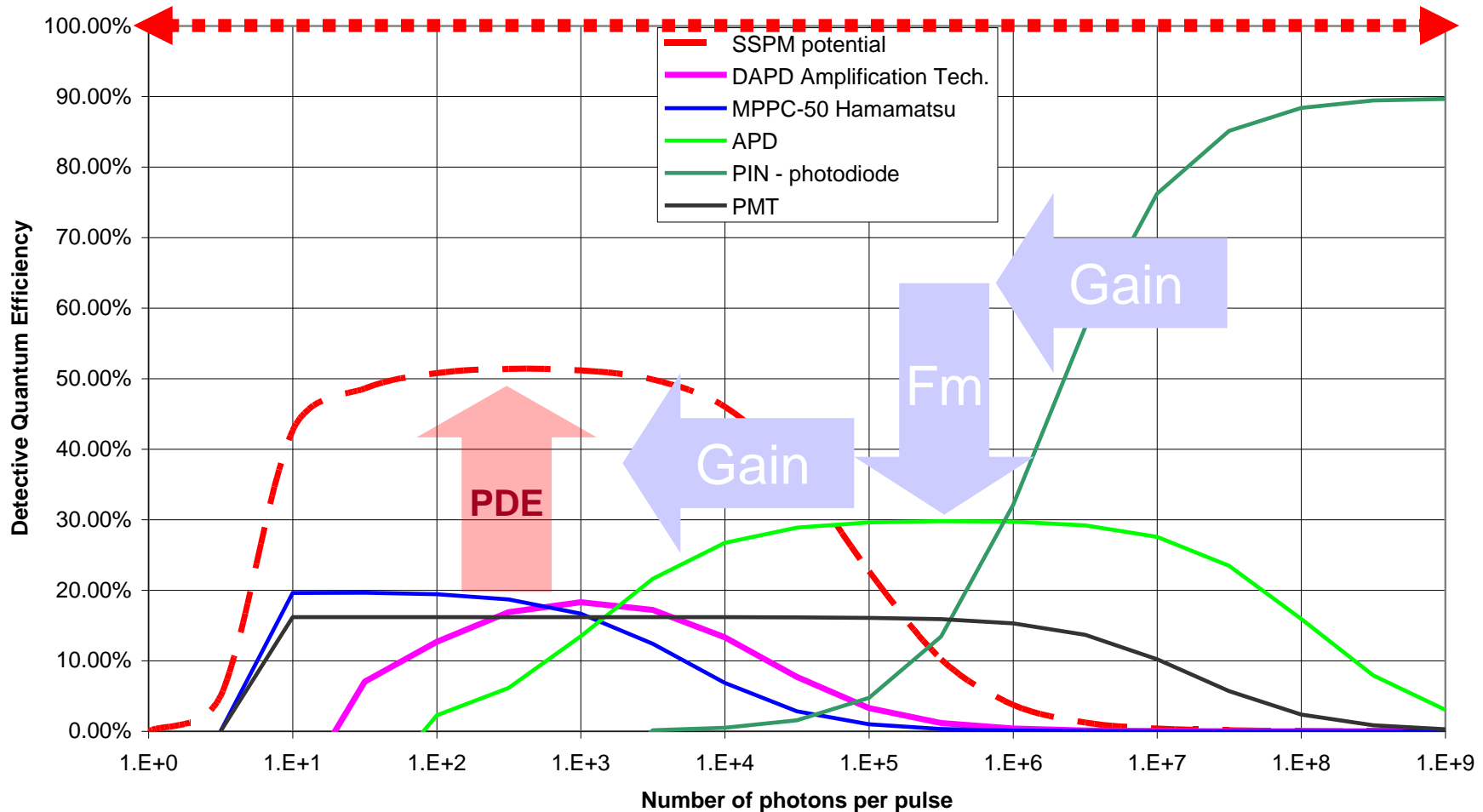
$$ENF_{total} = F_m \cdot F_{pde} \cdot F_{dcr} \cdot F_{ct} \cdot F_{ap} \cdot F_{nl}$$

$$DQE = \frac{1}{ENF_{total}}$$

Noise source	Key parameter	Typical values for SiPM	ENF expression	SiPM ENF	PMT ENF
Fluctuation of multiplication	Mean <i>gain</i> and standard deviation of <i>gain</i>	$\mu(\text{gain}) \sim 10^6$ $\sigma(\text{gain}) \sim 10^5$	$F_m = 1 + \frac{\sigma^2(\text{gain})}{\mu^2(\text{gain})}$	1.01	1.2
Crosstalk	Probability of crosstalk event <i>Pct</i>	5% – 40%	$F_{ct} = \frac{1}{1 + \ln(1 - Pct)}$	1.05 – 2	1
Afterpulsing	Probability of afterpulse <i>Pap</i>	5% – 20%	$F_{ap} = 1 + Pap$	1.05 – 1.2	1.01
Shot noise of dark counts	Dark count rate <i>DCR</i> Signal events in <i>Tpulse</i>	$10^5 - 10^7$ cps	$F_{dcr} = 1 + \frac{DCR \cdot Tpulse}{Nph \cdot PDE}$	1.01	1
Noise / losses of photon detections	Photon detection efficiency <i>PDE</i>	15% – 40%	$F_{pde} = \frac{1}{PDE}$	2.5 – 6.6	5
Total noise in linear dynamic range	Total <i>ENF_linear</i>	$ENF_linear = F_m \cdot F_{ct} \cdot F_{ap} \cdot F_{dcr} \cdot F_{pde}$		2.8 – 16	6
Pixel number nonlinearity	Mean number of possible single pixel firings <i>n</i>	$n = \frac{Nph \cdot PDE}{Npix}$; $ENF_{pix} = \frac{\exp(n) - 1}{n}$; binomial distribution			
Recovery time nonlinearity	Mean rate of possible single pixel firings λ	$\lambda = \frac{n}{Tpulse}$; $ENF_{rec} = 1 + \lambda \cdot Trec$; nonparalizable model			

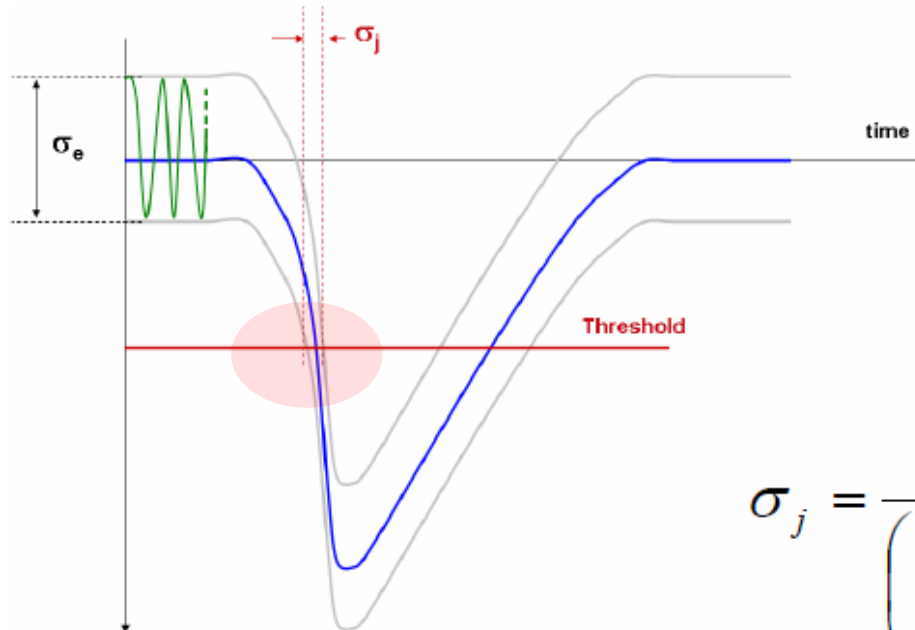
Performance in DQE – various detectors

SNR performance (relative to ideal) in nanosecond light pulse detection by 1mm² PDs



Time resolution

- Time resolution is combined as a sum of contributions
 - Transit time spread of photon arrival, avalanche triggering, avalanche development, and single electron response times
 - Jitter of signal amplitude fluctuations in a time scale



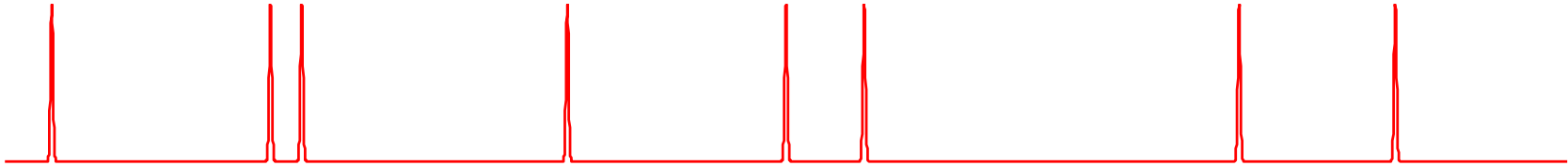
$$\sigma_j = \frac{\sigma_e}{\left(\frac{dV}{dt}\right)_{threshold}}$$

Filtered point process approach to amplitude fluctuations & time resolution

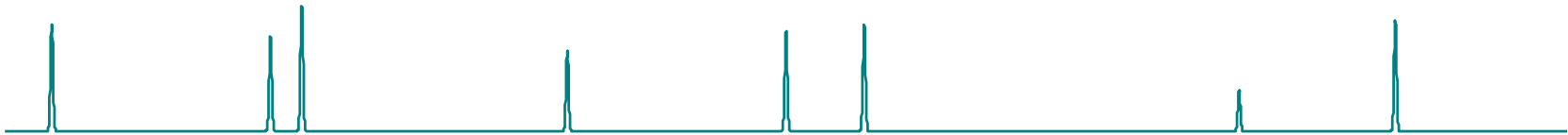


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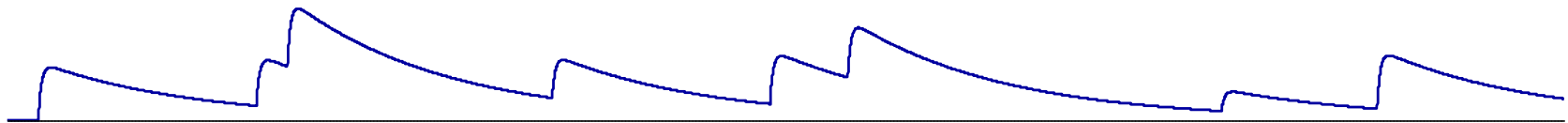
Point Process



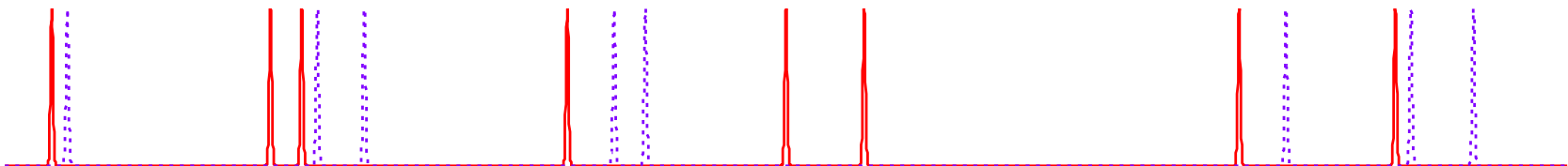
Marked Point Process



Filtered Output



Clastered Point Process



Clustered filtered point process model



- Time resolution includes all essential factors and combines performance in time response and PNR (ENF)

$$\sigma_t = \frac{\sqrt{\bar{N}_{pe} \cdot ENF_{gain} \cdot ENF_{sec} \cdot \left\{ \left[\rho_{ph} * \rho_{sptr} * \rho_{sec} * h_{ser}^2 \right](t) + \delta_{sci}^2 \cdot \bar{N}_{pe}^2 \cdot \left[\rho_{ph} * \rho_{sptr} * \rho_{sec} * h_{ser} \right]^2(t) \right\} + \frac{V_{noise}^2}{V_{ser}^2}}}{\bar{N}_{pe} \cdot \frac{d\left[\rho_{ph} * \rho_{sptr} * \rho_{sec} * h_{ser} \right](t)}{dt}}$$

$$= \frac{\left[\rho_{ph} * \rho_{sptr} * \rho_{sec} * h_{ser} \right](t)}{d\left[\rho_{ph} * \rho_{sptr} * \rho_{sec} * h_{ser} \right](t) / dt} \cdot \sqrt{\frac{1}{\bar{N}_{pe}} \cdot ENF_{gain} \cdot ENF_{sec} \cdot \left\{ \frac{\left[\rho_{ph} * \rho_{sptr} * \rho_{sec} * h_{ser}^2 \right](t)}{\left[\rho_{ph} * \rho_{sptr} * \rho_{sec} * h_{ser} \right]^2(t)} + \delta_{sci}^2 \right\} + \frac{V_{noise}^2}{V_{out}(t)^2}}$$

If light pulse is fast and SER is slow: $\left[\rho_{ph} * \rho_{sptr} * \rho_{sec} * h_{ser} \right](t) \approx h_{ser}(t) \Rightarrow$

$$\sigma_t \approx \tau_{rise} \cdot \sqrt{\frac{1}{\bar{N}_{ph}} \cdot ENF_{total} + \frac{V_{noise}^2}{V_{Thresh}^2}}$$

Time resolution: scintillation model & experiment



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Most popular & demanded case study: LYSO+MPPC

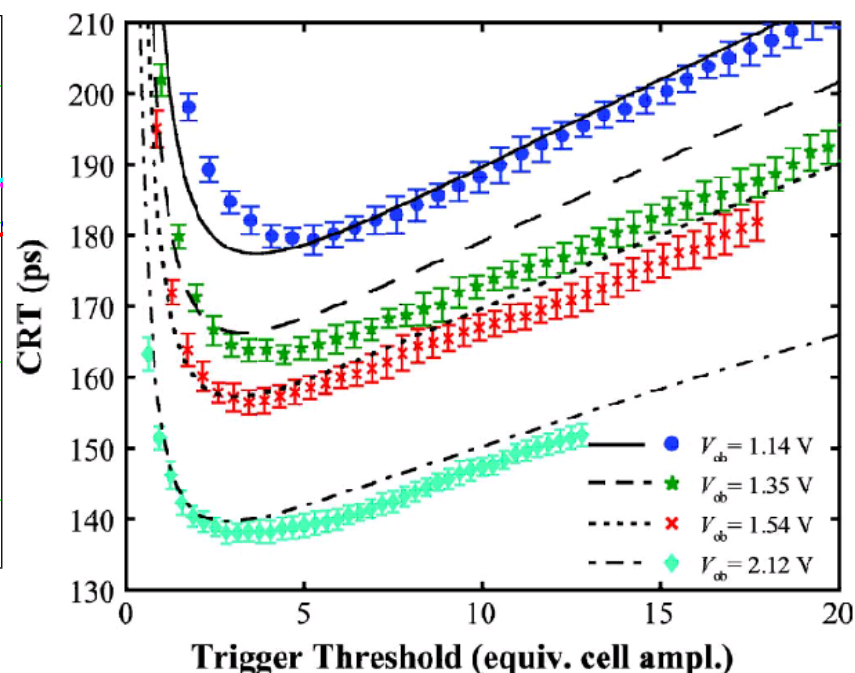
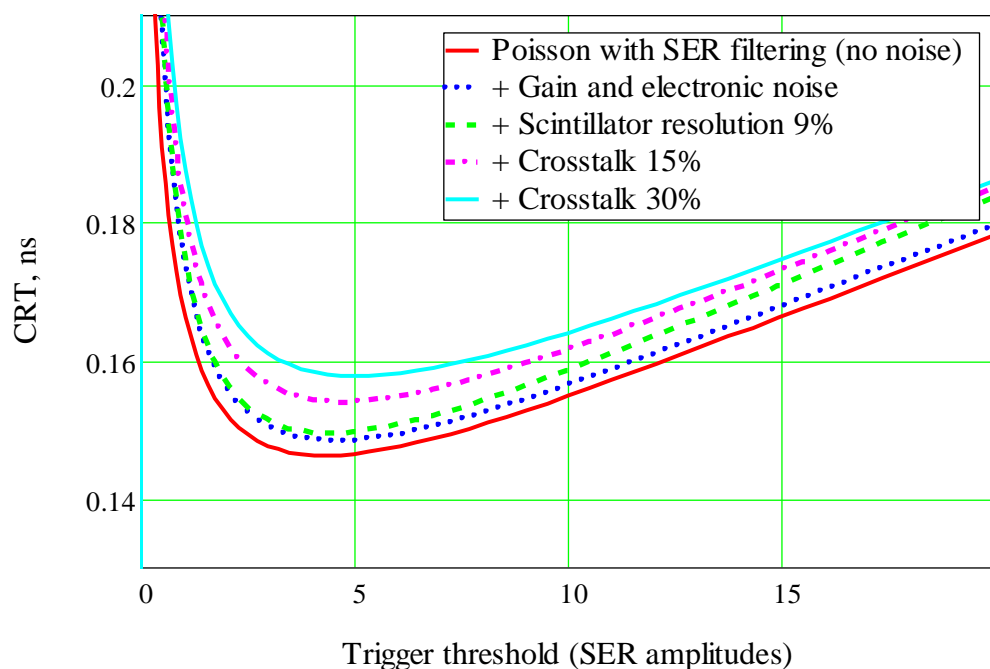
LYSO: 0.09 ns rise, 44 ns decay; 9% resolution

MPPC: $N_{pe}=3900$, ENFgain=1.015, Pct=0.14; SPTR=0.124 ns, $V_{noise}=0.32$ mV

S. Seifert et al, "A Comprehensive Model to Predict the Timing Resolution", TNS, 2012.

MPPC SER pulse shape – analytical expression (~ 1 ns rise, ~ 25 ns decay)

D. Marano et al, "Silicon Photomultipliers Electrical Model: Extensive Analytical Analysis" TNS 2014



Arbitrary signal detection: rectangular pulse response model

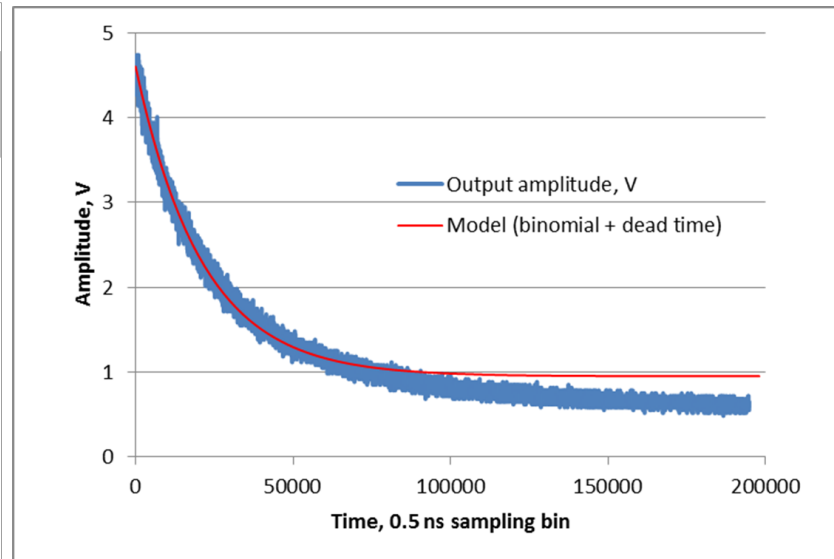
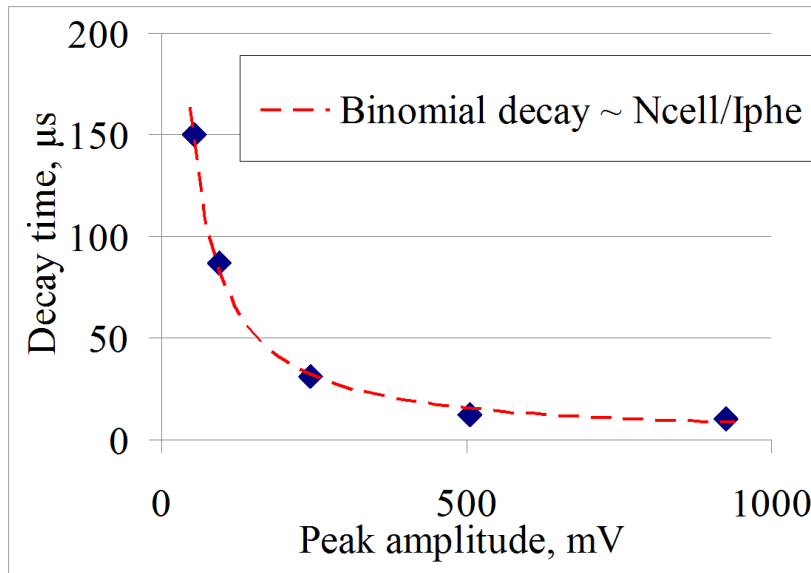
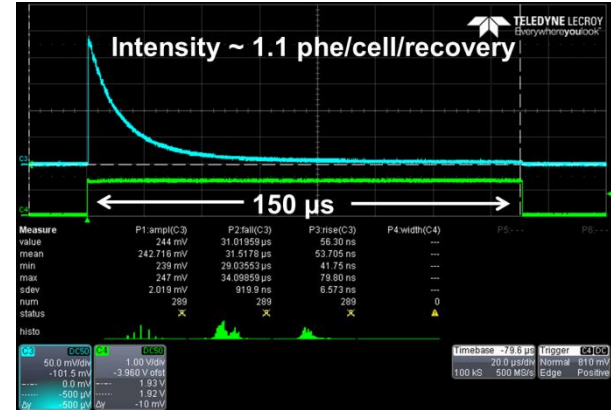
$$N_{fired}(t) = N_{cell} \cdot \exp\left(-\frac{N_{ph}(t) \cdot PDE}{N_{cell}}\right) \quad T_{pulse} < T_{rec} \quad \text{binomial distribution}$$

$$N_{fired}(t) = \frac{N_{ph}(t) \cdot PDE}{1 + \frac{N_{ph}(t) \cdot PDE \cdot T_{rec}}{N_{cell} \cdot T_{pulse}}} \quad T_{pulse} > T_{rec} \quad \text{non-paralizable dead time}$$

$$I_{fired}(t) = I_{binomial}(t) + I_{dead_time} \quad @ \quad N_{ph}(t) = I_{ph} \cdot t \quad (1)$$

$$I_{binomial}(t) = I_{ph} \cdot PDE \cdot \exp\left(-\frac{I_{ph} \cdot PDE \cdot t}{N_{cell}}\right) \quad I_{fired}(t=0) = I_{ph} \cdot PDE = I_{phe}$$

$$I_{dead_time} = \frac{I_{ph} \cdot PDE}{1 + \frac{I_{ph} \cdot PDE \cdot T_{rec}}{N_{cell}}} = const \quad T_{decay} = \frac{N_{cell}}{I_{ph} \cdot PDE} = \frac{N_{cell}}{I_{phe}} \quad (2)$$



Trends and prospects of SiPMs for BLM and accelerator applications



- 1. Introduction: the best photodetectors
- 2. Silicon Photomultipliers (SiPM) as new photon number resolving detectors
- 3. Benefits, drawbacks, and typical applications of SiPM
- 4. Evaluation studies of SiPMs for Beam Loss Monitoring
- 5. Modelling and analysis of comparative performance: SiPM vs PMT and APD
- 6. Trends and prospects of SiPM technology for BLM and accelerator applications

SiPM trends and advances



Market leaders

- ◆ Hamamatsu
- ◆ KETEK
- ◆ SensL
- ◆ FBK / AdvanSiD
- ◆ Excelitas / Perkin Elmer
- ◆ Philips (digital SiPM)

Design improvements (~ in a few year time scale)

- ◆ Higher Photon Detection Efficiency (30% → 70%)
- ◆ Lower crosstalk, lower afterpulsing (30% → 3%)
- ◆ Lower dark count rate (1000 → 40 Kcps/mm²)
- ◆ Faster SER, smaller pixel size (25 → 10 μm)
- ◆ Larger area, larger arrays (3x3 → 10x10mm², 4x4 → 16x16 channels)

Latest news from 2nd SiPM Advanced Workshop and Conf . on New Development s in Photodetection, 2014

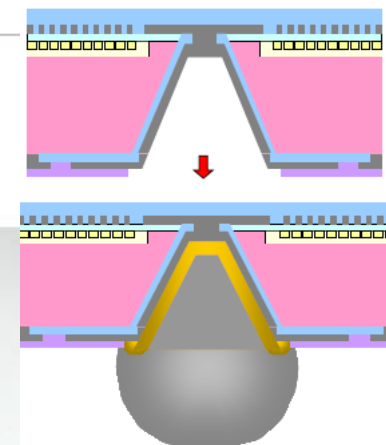
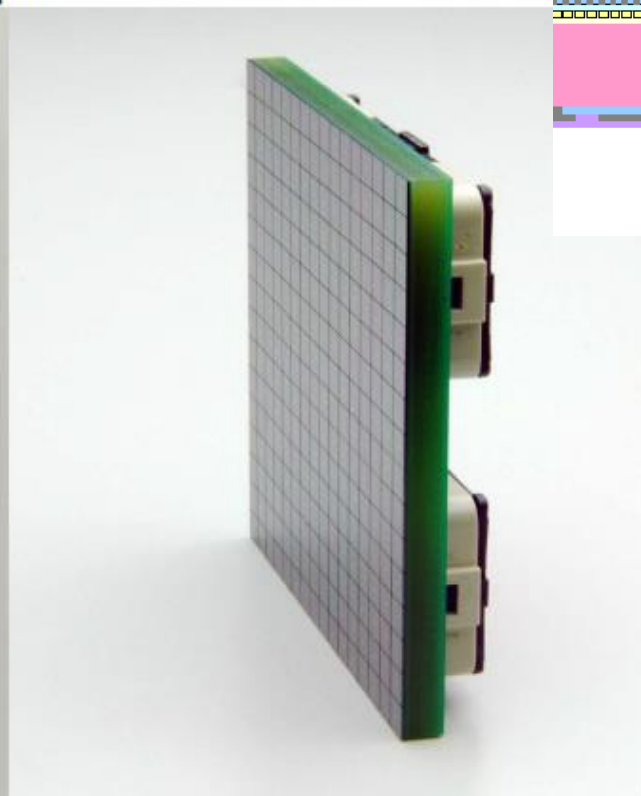
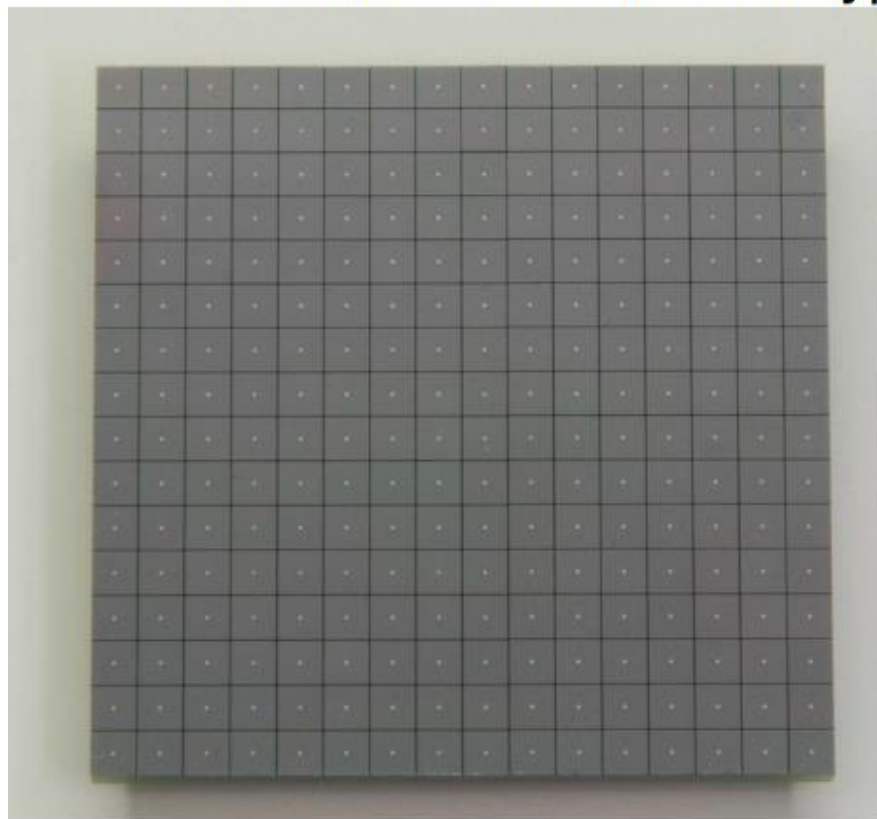
Hamamatsu: Through Silicon Vias



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2D MPPC Array with TSV

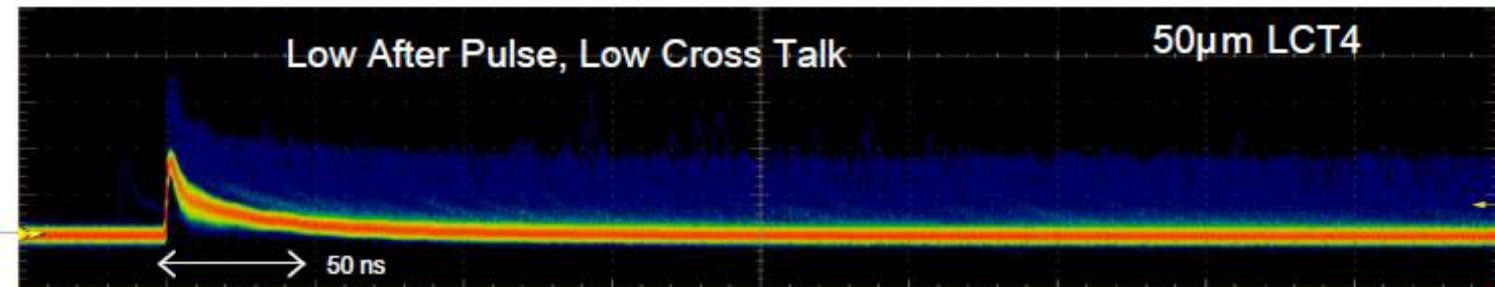
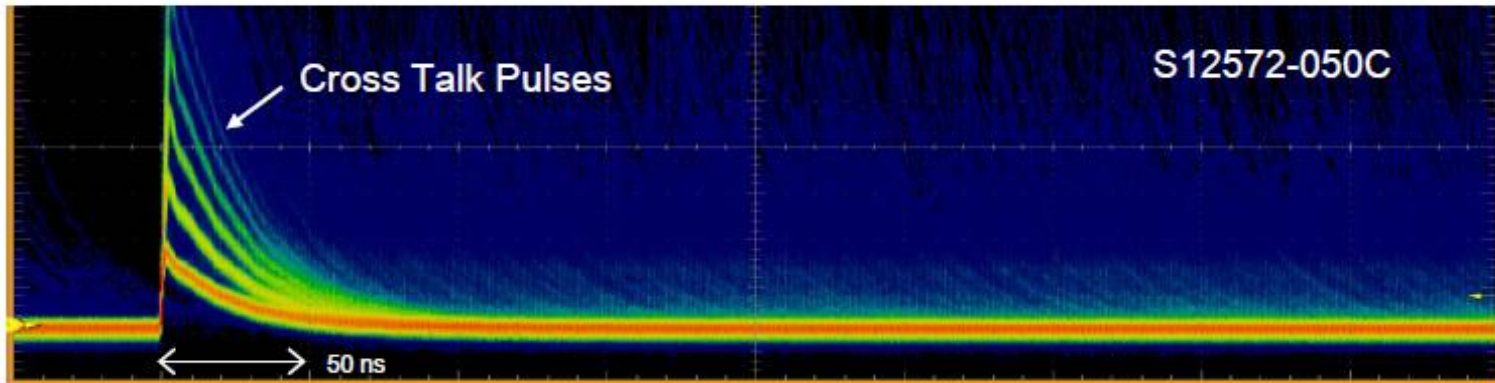
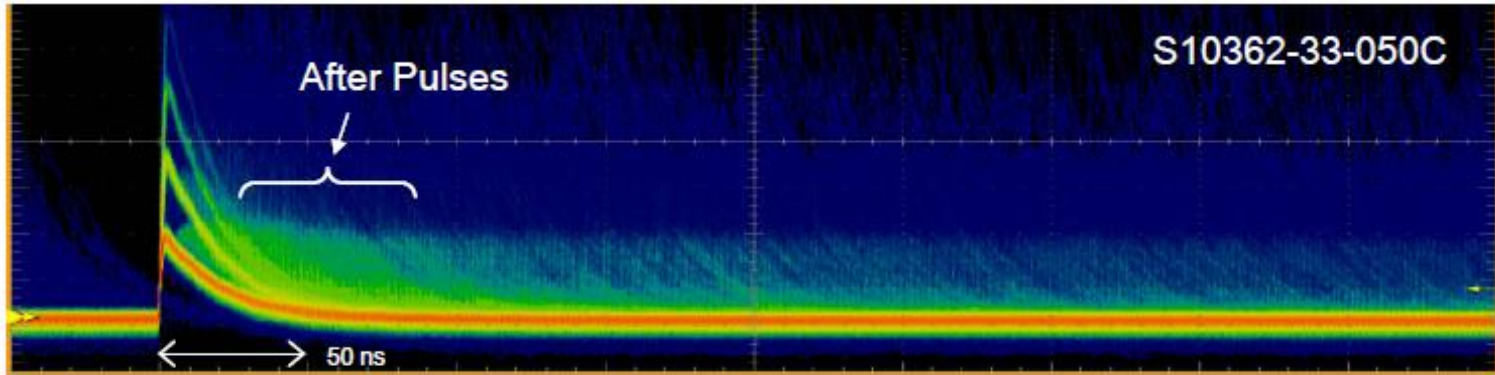
50 μ m pitch, 3x3mm chip,
16x16 channels with Connector type



Hamamatsu: Low Crosstalk & Afterpulsing

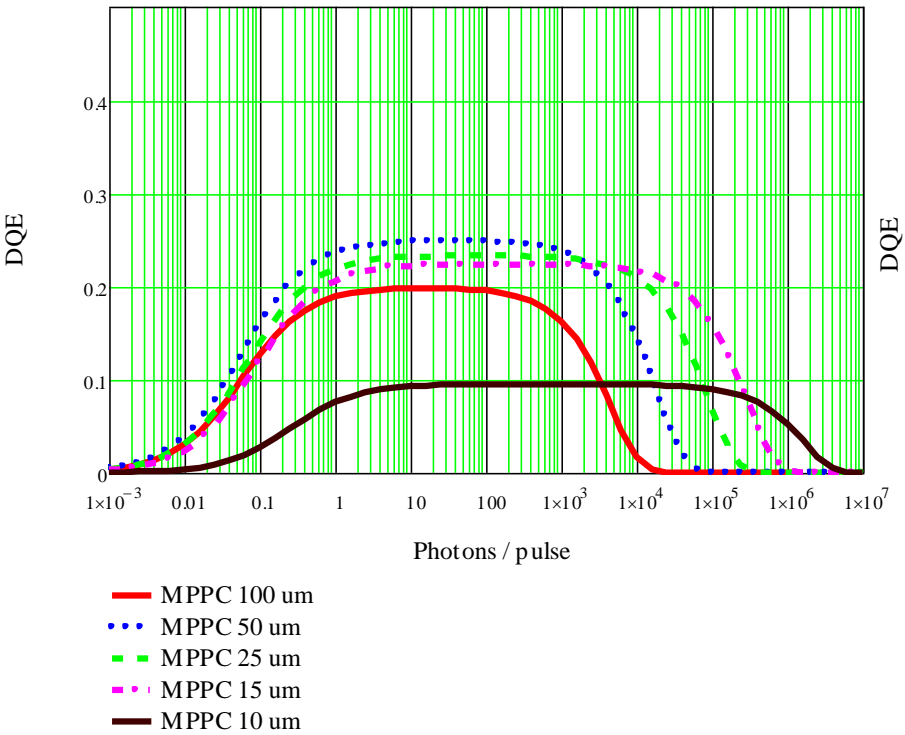


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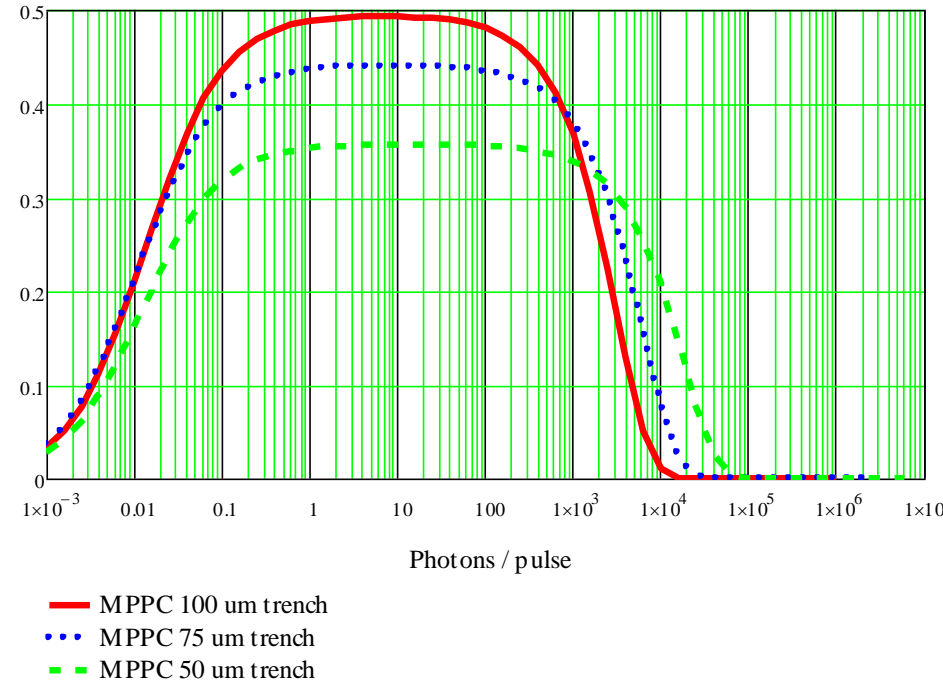


Performance in DQE - MPPC series

DQE of market MPPCs (3x3mm 100, 50, 25, 15, 10 um pixels)



DQE of newest MPPCs (3x3 mm 100, 75, 50, um pixels)

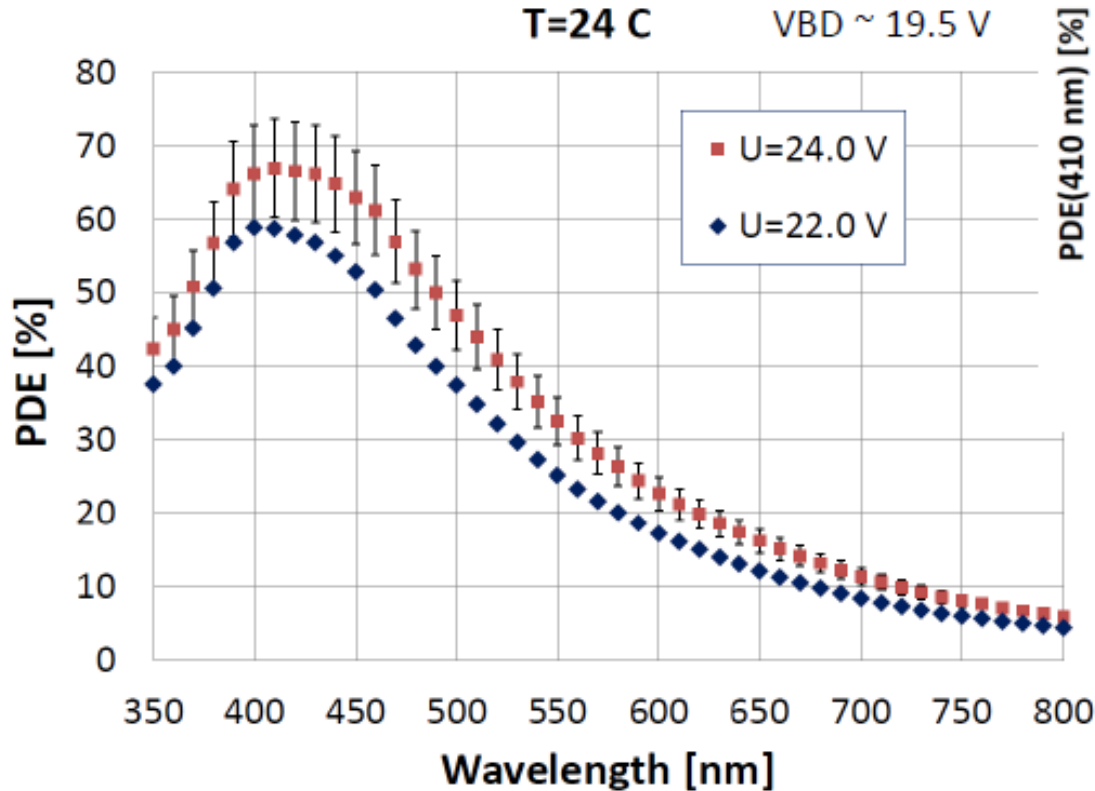


Pulse duration & detection time = 10 ns

KETEK

- Highest PDE @50 um pixels
- Various geometries
- 15 ... 100 um pixels

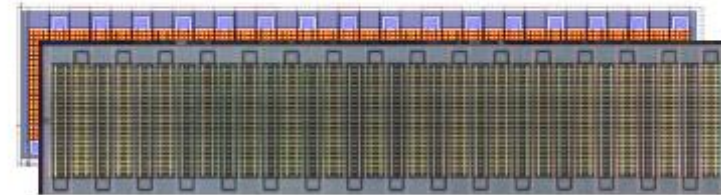
PM1150-Prototype: Measurements performed by CERN / Iouri Musienko
 (1.2 mm² active area, 50 μm cell pitch, 70% GE, no trench)



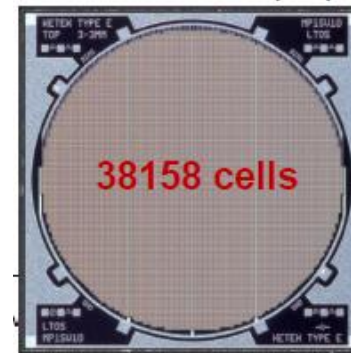
Type I (2013): 32 SiPM channels

Microcell Pitch: 60 μm x 57.5 μm

Quantity of cells: 88 per channel



45% PDE(410 nm) at 5% crosstalk!



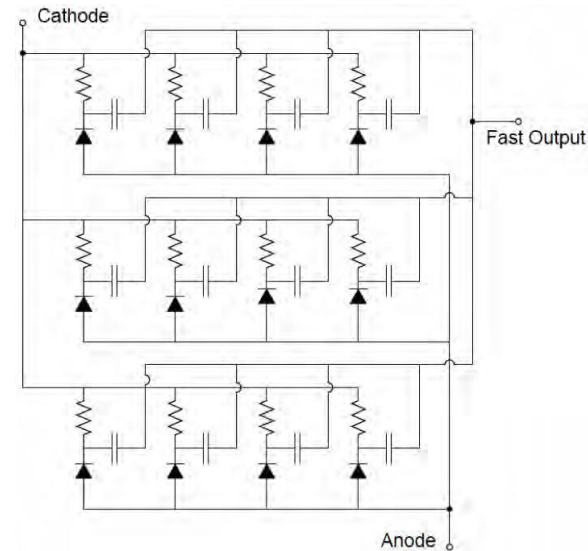
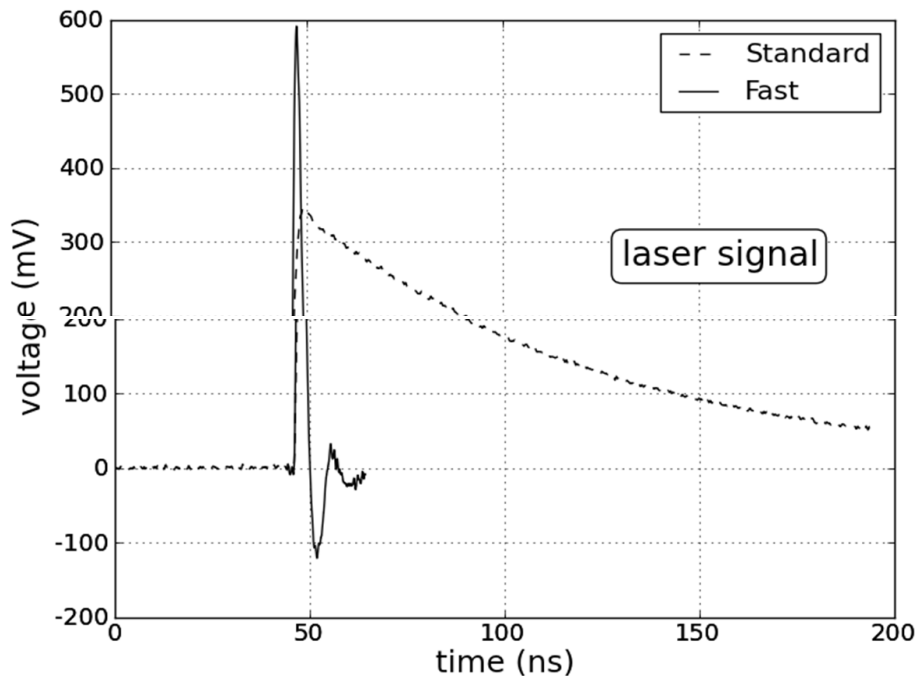
Chip Type E:

- Active area: 8.6 mm²
- 38158 cells - 15 μm pitch

EK GmbH

SensL

- Fast capacitive output
 - FWHM < 3.2 ns @ 6x6 mm²
- Large arrays / modules
- Low cost

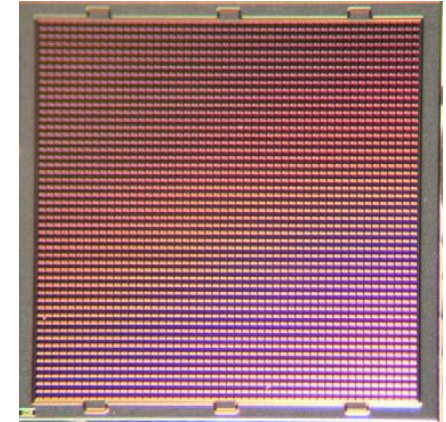
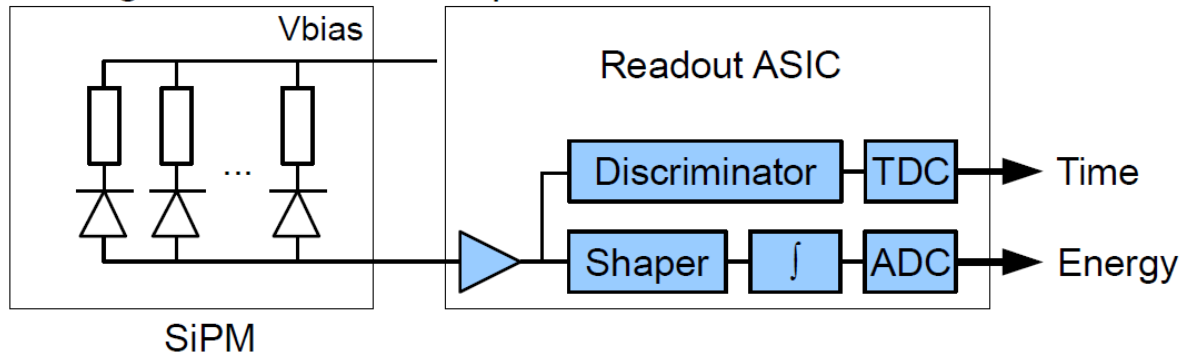


Philips: Digital SiPM (Modern active quenching SPAD array)

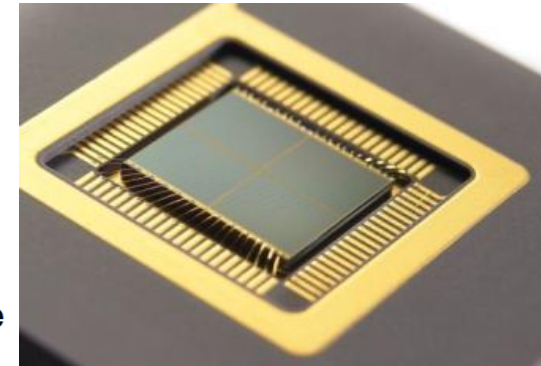
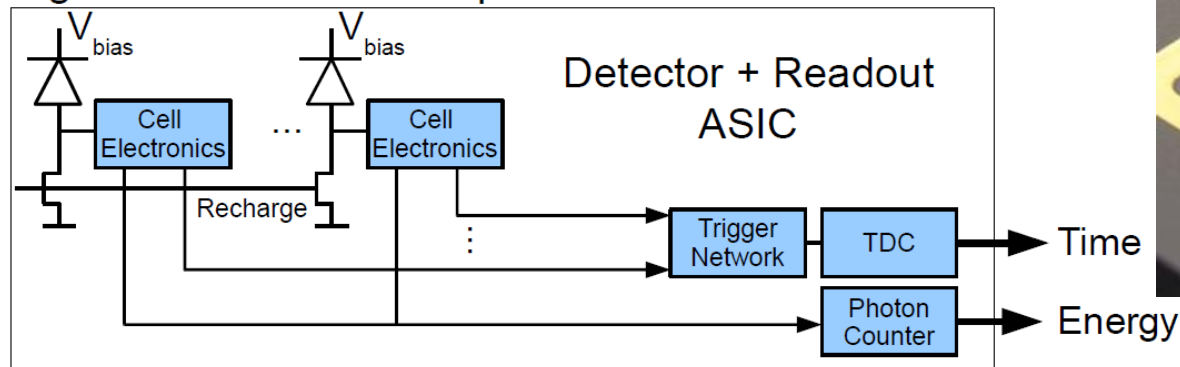
PHILIPS

Digital SiPM – The Concept

Analog Silicon Photomultiplier Detector



Digital Silicon Photomultiplier Detector



IEEE Nuclear Science Symposium / Medical Imaging Conference, Orlando, FL October 28, 2009

Summary on BLM with SiPM



■ BLM is one of the most challenging application for SiPM

◆ Benefits

- Practical & efficient (cost, compactness, Si reliability...)
- Perfect Transit Time Resolution (as is for now)
- Acceptable DQE within dynamic range (may be better)

◆ Drawbacks

- Upper margin of dynamic range is low (design improvement)
 - Number / density of pixels (\uparrow 10 times)
 - Pixel recovery time (\downarrow 10 times)
- Time response (bandwidth) (external measures)
 - Analog / digital SiPM output signal processing

■ BLM with SiPM: big problem with a chance to win

- ◆ And with a lot of space for new ideas, designs, and fun

Summary on SiPM

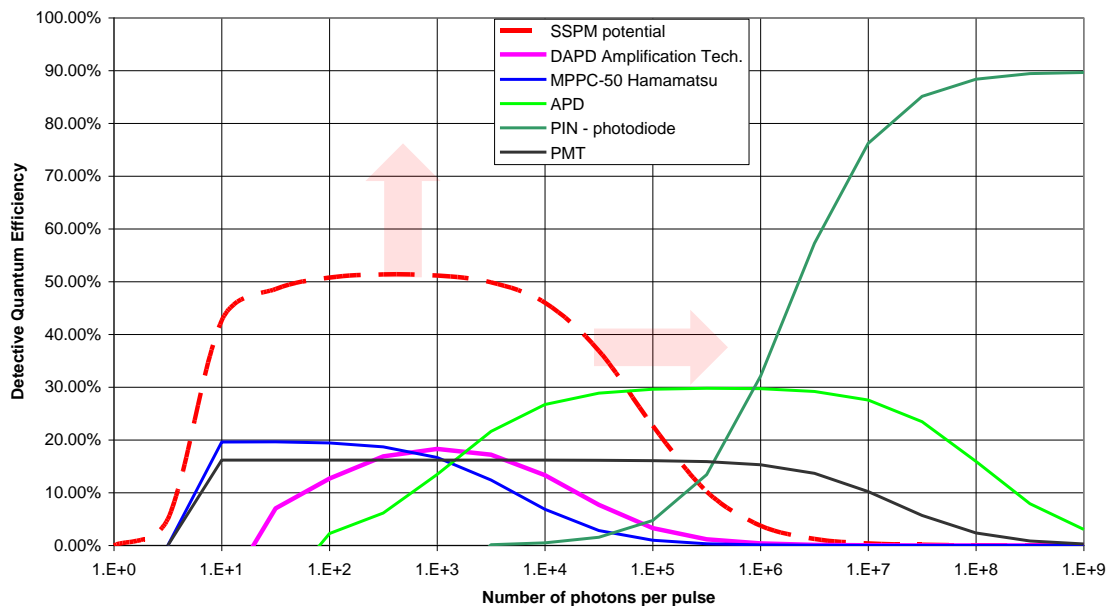
SiPM technology: breakthrough in photon detection

- ◆ Photon number resolution at room temperature
- ◆ Silicon technology / mass production / reliability / price
- ◆ Highly competitive in short ($< \mu\text{s}$) pulse detection
- ◆ Fast progress in improvements: DQE, Dynamic range, Timing

Welcome to SiPM applications

- ◆ Scintillation
- ◆ Cherenkov
- ◆ Laser pulse
- ◆ And much more...

SNR performance (relative to ideal) in nanosecond light pulse detection by 1mm^2 PDs



The end



■ Thank you for your attention

■ Questions?

Sergey.Vinogradov@liv.ac.uk